

mos integrated circuit μ PD78F0058,78F0058Y

8-BIT SINGLE-CHIP MICROCONTROLLERS

DESCRIPTION

The μ PD78F0058 is a product of the μ PD780058 Subseries in the 78K/0 Series and equivalent to the μ PD780058 with a flash memory in place of internal ROM. This device is incorporated with a flash memory which can be programmed without being removed from the substrate.

The μ PD78F0058Y is a products based on the μ PD78F0058, with an I²C bus interface supporting multimaster.

Functions are described in detail in the following user's manuals, which should be read when carrying out design work.

 μ PD780058, 780058Y Subseries User's Manual :U12013E 78K/0 Series User's Manual Instruction :U12326E

FEATURES

• Pin-compatible with mask ROM version (except VPP pin)

Flash memory : 60 Kbytes^{Note 1}
 Internal high-speed RAM : 1024 bytes
 Internal expansion RAM : 1024 bytes^{Note 2}

• Buffer RAM : 32 bytes

• Power supply voltage : VDD = 2.7 to 5.5 V

Notes 1. The flash memory capacity can be changed with the memory size switching register (IMS).

2. The internal expansion RAM capacity can be changed with the internal expansion RAM size switching register (IXS).

Remark For the differences between the flash memory versions and the mask ROM versions, refer to

1. DIFFERENCES BETWEEN μ PD78F0058, 78F0058Y, AND MASK ROM VERSION.

APPLICATION FIELDS

Car audio systems, cellular phones, pagers, printers, AV equipment, cameras, PPCs, vending machines, etc.

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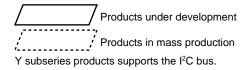


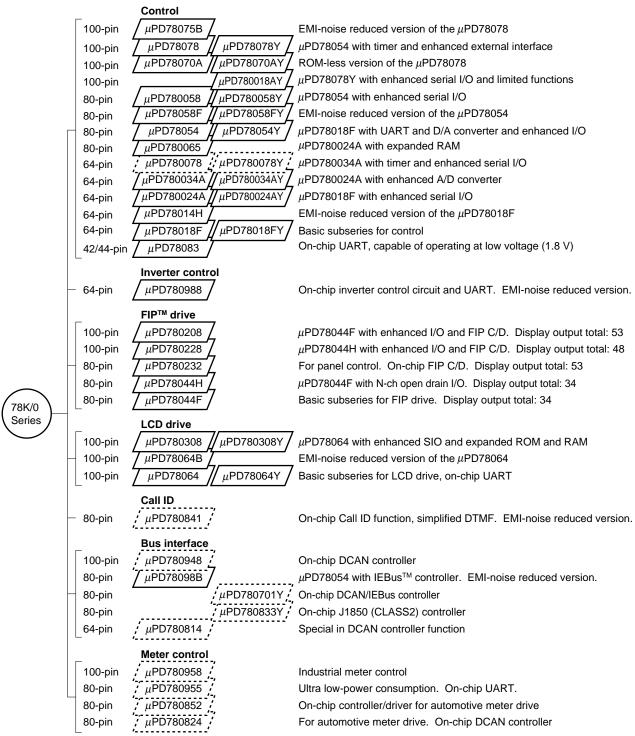
ORDERING INFORMATION

| | Part Number | Package |
|---|--|---|
| | μPD78F0058GC-8BT | 80-pin plastic QFP (14 × 14 mm) |
| | μPD78F0058GK-BE9 | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm, resin thickness 1.05 mm) |
| * | μPD78F0058GK-9EU ^{Note} | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm, resin thickness 1.0 mm) |
| | μPD78F0058YGC-8BT | 80-pin plastic QFP $(14 \times 14 \text{ mm})$ |
| | μPD78F0058YGK-BE9 | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm, resin thickness 1.05 mm) |
| * | μ PD78F0058YGK-9EU ^{Note} | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm, resin thickness 1.0 mm) |
| | Note Under development | |

★ 78K/0 SERIES LINEUP

The products in the 78K/0 Series are listed below. The names enclosed in boxes are subseries name.







The major functional differences among the subseries are listed below.

| Function | | ROM | | Tir | ner | | 8-Bit | 10-Bit | 8-Bit | Serial | 1/0 | V _{DD} MIN. | External |
|------------------|------------|--------------|-------|--------|-------|------|-------|--------|-------|------------------------------------|-----|----------------------|-----------|
| Subseries Name | | Capacity | 8-bit | 16-bit | Watch | WDT | A/D | A/D | D/A | Interface | I/O | Value | Expansion |
| Control | μPD78075B | 32 K to 40K | 4 ch | 1 ch | 1 ch | 1 ch | 8 ch | _ | 2 ch | 3 ch (UART: 1 ch) | 88 | 1.8 V | √ |
| | μPD78078 | 48 K to 60K | | | | | | | | | | | |
| | μPD78070A | _ | | | | | | | | | 61 | 2.7 V | |
| | μPD780058 | 24 K to 60 K | 2 ch | | | | | | | 3 ch (time-division UART: 1 ch) | 68 | 1.8 V | |
| | μPD78058F | 48 K to 60 K | | | | | | | | 3 ch (UART: 1 ch) | 69 | 2.7 V | |
| | μPD78054 | 16 K to 60 K | | | | | | | | | | 2.0 V | |
| | μPD780065 | 40 K to 48 K | | | | | | | _ | 4 ch (UART: 1 ch) | 60 | 2.7 V | |
| | μPD780078 | 48 K to 60 K | | 2 ch | | | _ | 8 ch | | 3 ch (UART: 2 ch) | 52 | 1.8 V | |
| | μPD780034A | 8 K to 32 K | | 1 ch | | | | | | 3 ch (UART: 1 ch) | 51 | | |
| | μPD780024A | | | | | | 8 ch | _ | | | | | |
| | μPD78014H | | | | | | | | | 2 ch | 53 | | |
| | μPD78018F | 8 K to 60 K | | | | | | | | | | | |
| | μPD78083 | 8 K to 16 K | | _ | _ | | | | | 1 ch (UART: 1 ch) | 33 | | _ |
| Inverter control | μPD780988 | 16 K to 60 K | 3 ch | Note | 1 | 1 ch | _ | 8 ch | - | 3 ch (UART: 2 ch) | 47 | 4.0 V | √ |
| FIP | μPD780208 | 32 K to 60 K | 2 ch | 1 ch | 1 ch | 1 ch | 8 ch | _ | _ | 2 ch | 74 | 2.7 V | - |
| drive | μPD780228 | 48 K to 60 K | 3 ch | _ | _ | | | | | 1 ch | 72 | 4.5 V | |
| | μPD780232 | 16 K to 24 K | | | | | 4 ch | | | 2 ch | 40 | | |
| | μPD78044H | 32 K to 48 K | 2 ch | 1 ch | 1ch | | 8 ch | | | 1 ch | 68 | 2.7 V | |
| | μPD78044F | 16 K to 40 K | | | | | | | | 2 ch | | | |
| LCD drive | μPD780308 | 48 K to 60 K | 2 ch | 1 ch | 1ch | 1 ch | 8 ch | _ | _ | 3 ch (time-division UART: 1 ch) | 57 | 2.0 V | _ |
| | μPD78064B | 32 K | | | | | | | | 2 ch (UART: 1 ch) | | | |
| | μPD78064 | 16 K to 32 K | | | | | | | | | | | |
| Call ID | μPD780841 | 24 K to 32 K | 1 ch | 1 ch | 1 ch | 1 ch | 2 ch | _ | _ | 2 ch (UART: 1 ch) | 57 | 2.7 V | - |
| Bus | μPD780948 | 60 K | 2 ch | 2 ch | 1 ch | 1 ch | 8 ch | _ | _ | 3 ch (UART: 1 ch) | 79 | 4.0 V | √ |
| interface | μPD78098B | 40 K to 60 K | | 1 ch | | | | | 2 ch | | 69 | 2.7 V | _ |
| supported | μPD780814 | 32 K to 60 K | | 2 ch | | | 12 ch | | _ | 2 ch (UART: 1 ch) | 46 | 4.0 V | |
| Meter | μPD780958 | 48 K to 60 K | 4 ch | 2 ch | _ | 1 ch | _ | _ | _ | 2 ch (UART: 1 ch) | 69 | 2.2 V | _ |
| control | μPD780955 | 40 K | 6 ch | 1 ch | | | 1 ch | | | 2 ch (UART: 2 ch) | 50 | | |
| | μPD780852 | 32 K to 40 K | 3 ch | | 1 ch | | 5 ch | | | 3 ch (UART: 1 ch) | 56 | 4.0 V | |
| | μPD780824 | 32 K to 60 K | | | | | | | | 2 ch (UART: 1 ch) | 59 | 4.0 V | |

Note 16-bit timer: 2 channels 10-bit timer: 1 channel



The major functional differences among the Y subseries are shown below.

| | Function | ROM Capacity | Configuration of Serial Inte | rface | I/O | VDD MIN. |
|--------------|-------------|--------------|--|--------------------------------------|-----|----------|
| Subserie | es Name | | | | | Value |
| Control | μPD78078Y | 48 K to 60 K | 3-wire/2-wire/I ² C 3-wire with automatic transmit/receive function | : 1 ch | 88 | 1.8 V |
| | μPD78070AY | _ | 3-wire/UART | : 1 ch | 61 | 2.7 V |
| | μPD780018AY | 48 K to 60 K | 3-wire with automatic transmit/receive function Time-division 3-wire | : 1 ch | 88 | |
| | μPD780058Y | 24 K to 60 K | l ² C bus (multimaster supported) 3-wire/2-wire/l ² C 3-wire with automatic transmit/receive function 3-wire/time-division UART | : 1 ch : 1 ch : 1 ch : 1 ch | 68 | 1.8 V |
| | μPD78058FY | 48 K to 60 K | 3-wire/2-wire/I ² C 3-wire with automatic transmit/receive function | : 1 ch | 69 | 2.7 V |
| | μPD78054Y | 16 K to 60 K | 3-wire/UART | : 1 ch | | 2.0 V |
| | μPD780078Y | 48 K to 60 K | 3-wire UART 3-wire/UART I ² C bus (multimaster supported) | : 1 ch : 1 ch : 1 ch : 1 ch | 52 | 1.8 V |
| | μPD780034AY | 8 K to 32 K | UART | : 1 ch | 51 | 1.8 V |
| | μPD780024AY | 1 | 3-wire I ² C bus (multimaster supported) | : 1 ch : 1 ch | | |
| | μPD78018FY | 8 K to 60 K | 3-wire/2-wire/I ² C 3-wire with automatic transmit/receive function | : 1 ch : 1 ch | 53 | |
| LCD drive | μPD780308Y | 48 K to 60 K | 3-wire/2-wire/I ² C 3-wire/time-division UART 3-wire | : 1 ch : 1 ch : 1 ch | 57 | 2.0 V |
| | μPD78064Y | 16 K to 32 K | 3-wire/2-wire/l ² C 3-wire/UART | : 1 ch : 1 ch | | |

Remark The functions other than the serial interface are common to the Subseries without Y.

OVERVIEW OF FUNCTIONS

| | Product Name | μPD78F0058 | μPD78F0058Y | | | | |
|---------------------|------------------------------------|--|--------------------------------------|--|--|--|--|
| Item | | | | | | | |
| Internal | Flash memory | 60 Kbytes | | | | | |
| memory | High-speed RAM | 1,024 bytes | | | | | |
| | Buffer RAM | 32 bytes | | | | | |
| | Expanded RAM | 1,024 bytes | | | | | |
| Memory sp | ace | 64 Kbytes | | | | | |
| General reg | gisters | 8 bits \times 32 registers (8 bits \times 8 registers \times 4 | banks) | | | | |
| Minimum instruction | When main system clock is selected | 0.4 μs/0.8 μs/1.6 μs/3.2 μs/6.4 μs/12.8 μs (@ | 25.0 MHz operation) | | | | |
| execution time | When subsystem clock is selected | 122 μs (@32.768 kHz operation) | | | | | |
| Instruction | set | 16-bit operation Multiply/divide (8 bits × 8 bits, 16 bits ÷ 8 bits an inputation (set, reset, test, Boolean in BCD adjust, etc. | | | | | |
| I/O ports | | Total: 68 • CMOS input: 2 • CMOS I/O: 62 • N-ch open-drain I/O: 4 | | | | | |
| A/D conver | ter | 8-bit resolution × 8 channels (VDD = 2.7 to 5.5 V) | | | | | |
| D/A conver | ter | • 8-bit resolution × 2 channels (V _{DD} = 2.7 to 5.5 V) | | | | | |
| Serial inter | face | 3-wire serial I/O/SBI/2-wire serial | 3-wire serial I/O/2-wire serial I/O/ | | | | |
| | | I/O mode selectable: 1 channel 3-wire serial I/O mode (automatic data transmit/receive function for up to 32 bytes provided on chip): 1 channel 3-wire/serial I/O/UART mode (time division transfer function provided on chip) selectable: 1 channel | | | | | |
| Timers | | 16-bit timer/event counter: 1 channel 8-bit timer/event counter: 2 channels Watch timer: 1 channel Watchdog timer: 1 channel | | | | | |
| Timer outp | uts | 3 (14-bit PWM output × 1) | | | | | |
| Clock outpo | ut | 19.5 kHz, 39.1 kHz, 78.1 kHz, 156 kHz, 313 kHz, 625 kHz, 1.25 MHz, 2.5 MHz, 5.0 MHz (@5.0 MHz operation with main system clock) 32.768 kHz (@32.768 kHz operation with subsystem clock) | | | | | |
| Buzzer out | put | 1.2 kHz, 2.4 kHz, 4.9 kHz, 9.8 kHz (@5.0 MHz operation with main system clock) | | | | | |
| Vectored | Maskable | Internal: 13, External: 6 | | | | | |
| interrupt | Non-maskable | Internal: 1 | | | | | |
| sources | Software | 1 | | | | | |
| Test inputs | | Internal: 1, External: 1 | | | | | |
| Supply volt | age | V _{DD} = 2.7 to 5.5 V | | | | | |
| Operating a | ambient temperature | $T_A = -40 \text{ to } +85^{\circ}\text{C}$ | | | | | |
| Package | - | 80-pin plastic QFP (14 × 14 mm) 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.05 mm) 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.0 mm) | | | | | |

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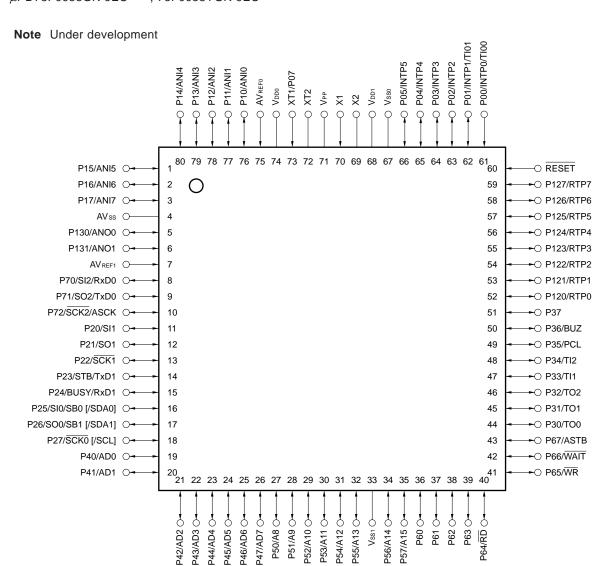
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1. PIN CONFIGURATION (TOP VIEW)

- 80-pin plastic QFP (14 \times 14 mm) μ PD78F0058GC-8BT, 78F0058YGC-8BT
- 80-pin plastic TQFP (fine pitch) (12 \times 12 mm, resin thickness 1.05 mm) μ PD78F0058GK-BE9, 78F0058YGK-BE9
- * 80-pin plastic TQFP (fine pitch) (12 \times 12 mm, resin thickness 1.0 mm) μ PD78F0058GK-9EU^{Note}, 78F0058YGK-9EU^{Note}



- Cautions 1. Connect the VPP pin directly to Vsso or Vss1 in normal operation mode.
 - 2. Connect the AVss pin to Vsso.
- **Remarks 1.** []: μ PD78F0058Y only.
 - 2. When the microcontroller is used in applications where the noise generated inside the microcontroller needs to be reduced, the implementation of noise reduction measures, such as supplying voltage to V_{DD0} and V_{DD1} individually and connecting V_{SS0} and V_{SS1} to different ground lines, is recommended.



PIN IDENTIFICATION

 $\overline{\mathsf{RD}}$: Read Strobe A8 to A15 : Address Bus AD0 to AD7 : Address/Data Bus RESET : Reset

ANI0 to ANI7 : Analog Input RTP0 to RTP7 : Real-Time Output Port

ANO0, ANO1 : Analog Output RxD0, RxD1 : Receive Data **ASCK** : Serial Bus : Asychronous Serial Clock SB0, SB1 **ASTB** : Address Strobe SCK0 to SCK2 : Serial Clock

AVREFO, AVREF1 : Analog Reference Voltage SCL : Serial Clock **AVss** SDA0, SDA1 : Serial Data : Analog Ground **BUSY** : Busy SI0 to SI2 : Serial Input

SO0 to SO2 : Serial Output BUZ : Buzzer Clock

INTP0 to INTP5 : Interrupt from Peripherals STB : Strobe P00 to P05, P07: Port 0 : Timer Input TI00, TI01 P10 to P17 : Port 1 TI1, TI2 : Timer Input P20 to P27 : Port 2 TO0 to TO2 : Timer Output P30 to P37 : Port 3 TxD0, TxD1 : Transmit Data P40 to P47 : Port 4 VDD0, VDD1 : Power Supply

P50 to P57 : Port 5 V_{PP} : Programming Power Supply

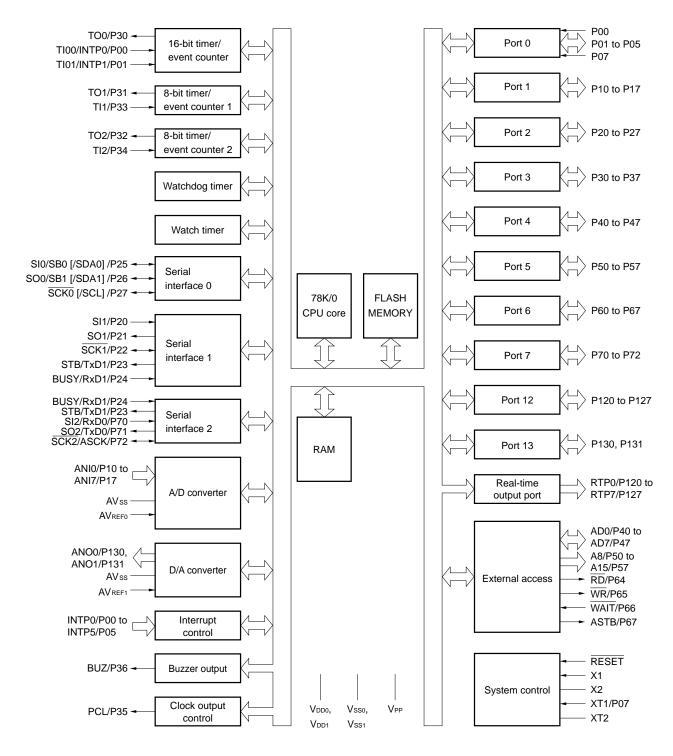
: Ground P60 to P67 : Port 6 Vsso, Vss1 WAIT P70 to P72 : Port 7 : Wait

WR P120 to P127 : Port 12 : Write Strobe

X1, X2 P130, P131 : Port 13 : Crystal (Main System Clock)

PCL XT1, XT2 : Crystal (Subsystem Clock) : Programmable Clock

2. BLOCK DIAGRAM



Remark []: μ PD78F0058Y only.

3. DIFFERENCES BETWEEN μ PD78F0058, 78F0058Y, AND MASK ROM VERSIONS

The μ PD78F0058 and 78F0058Y are products provided with a flash memory which enables on-board reading, erasing, and rewriting of programs with device mounted on target system. The functions of the μ PD78F0058 and 78F0058Y (except the functions specified for flash memory and mask option of P60 to P63 pins) can be made the same as those of the mask ROM versions by setting the memory size switching register (IMS) and internal expansion RAM size switching register (IXS).

Table 3-1 shows the differences between the flash memory version (μ PD78F0058, 78F0058Y) and the mask ROM versions (μ PD780053, 780054, 780055, 780056, 780058, 780053Y, 780054Y, 780055Y,780056Y, and 780058Y).

Table 3-1. Differences between μ PD78F0058, 78F0058Y and Mask ROM Versions

| | Item | μPD78F0058 | μPD78F0058Y | Mask ROM Versions | | |
|-----|---|------------------------------|--------------|--|-------------------------|--|
| | | | | μPD780058 Subseries | μPD780058Y Subseries | |
| | Internal ROM structure | Flash memory | | Mask ROM | | |
| | Internal ROM capacity | 60 Kbytes | | μΡD780053, 780053Y : 24 Kbytes μΡD780054, 780054Y : 32 Kbytes μΡD780055, 780055Y : 40 Kbytes μΡD780056, 780056Y : 48 Kbytes μΡD780058, 780058Y : 60 Kbytes μΡD780053, 780053Y : None μΡD780054, 780054Y : None μΡD780055, 780055Y : None μΡD780056, 780056Y : None μΡD780058, 780056Y : None μΡD780058, 780058Y : 1024 bytes | | |
| | Internal expansion RAM capacity | 1024 bytes | | | | |
| | Internal ROM capacity changeable/not changeable with memory size switching register (IMS) | Changeable Note | 1 | | | |
| Ī | Internal expansion RAM capacity changeable/not changeable with internal expansion RAM size switching register (IXS) | Changeable Note 2 | 2 | Not changeable | | |
| . [| Supply voltage | V _{DD} = 2.7 to 5.5 | V | V _{DD} = 1.8 to 5.5 \ | / | |
| | IC pin | Not provided | | Provided | | |
| | V _{PP} pin | Provided | | Not provided | | |
| | P60 to P63 pin mask option with internal pull-up resistors | Not provided | | Provided | | |
| . | Serial interface (SBI) | Provided | Not provided | Provided | Not provided | |
| . [| Serial interface (I ² C) | Not provided | Provided | Not provided | Provided | |

- Notes 1. Flash memory is set to 60 Kbytes by RESET input.
 - 2. Internal expansion RAM is set to 1024 bytes by RESET input.

Caution The noise resistance and noise radiation differ between flash memory versions and mask ROM versions. When considering the replacement of flash memory versions with mask ROM versions in the process from trial manufacturing to mass production, adequate evaluation should be carried out using CS products (not ES products) of mask ROM versions.

Remark Only the μ PD780058, 780058Y, 78F0058, and 78F0058Y are provided with IXS.



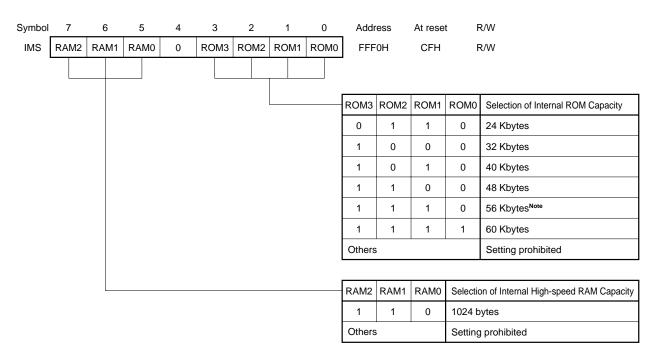
3.1 Memory Size Switching Register (IMS)

This register sets a part of internal memory unused by software. The memory mapping can be made the same as that of mask ROM versions with different types of internal memory (ROM and RAM) by setting the memory size switching register (IMS).

The IMS is set with an 8-bit memory manipulation instruction.

RESET input sets the IMS to CFH.

Figure 3-1. Format of Memory Size Switching Register



Note When using external device expansion function, set the internal ROM capacity to less than 56 Kbytes.

Table 3-2 shows the IMS set value to make the memory mapping the same as those of mask ROM versions.

Table 3-2. Set Value of Memory Size Switching Register

| Target Mask ROM Versions | IMS Set Value |
|--------------------------|---------------|
| μPD780053, 780053Y | C6H |
| μPD780054, 780054Y | C8H |
| μPD780055, 780055Y | CAH |
| μPD780056, 780056Y | ССН |
| μPD780058, 780058Y | CFH |

3.2 Internal Expansion RAM Size Switching Register (IXS)

This register sets the internal expansion RAM capacity by software. The memory mapping can be made the same as that of mask ROM versions with different types of internal expansion RAM by setting the internal expansion RAM size switching register (IXS).

The IXS is set with an 8-bit memory manipulation instruction.

RESET input sets the IXS to 0AH.

Figure 3-2. Format of Internal Expansion RAM Size Switching Register

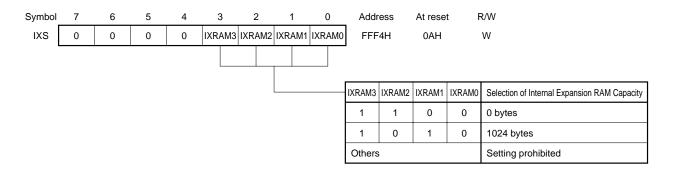


Table 3-3 shows the IXS set value to make the memory mapping the same as those of mask ROM versions.

Table 3-3. Set Value of Internal Expansion RAM Size Switching Register

| Target Mask ROM Versions | IMS Set Value |
|--------------------------|---------------|
| μPD780053, 780053Y | 0CH |
| μPD780054, 780054Y | |
| μPD780055, 780055Y | |
| μPD780056, 780056Y | |
| μPD780058, 780058Y | 0AH |



4. PIN FUNCTIONS

4.1 Port Pins (1/2)

| Pin Name | I/O | | Function | After Reset | Alternate Function |
|------------|-------|---|--|-----------------|-----------------------|
| P00 | Input | Port 0 | Input only | Input | INTP0/TI00 |
| P01 | I/O | 7-bit input/output port | Input/output can be specified in 1-bit units. | Input | INTP1/TI01 |
| P02 | I/O | | When used as an input port, an on-chip pull-up | | INTP2 |
| P03 | | | resistor can be specified by means of software. | | INTP3 |
| P04 | | | | | INTP4 |
| P05 | Input | | | | INTP5 |
| P07Note 1 | Input | - | Input only | Input | XT1 |
| P10 to P17 | I/O | Port 1 8-bit input/output port Input/output can be specified by means of so | port, an on-chip pull-up resistor can be | Input | ANI0 to ANI7 |
| P20 | I/O | I/O Port 2 | | Input | SI1 |
| P21 | | 8-bit input/output port | | SO1 | |
| P22 | | Input/output can be specified When used as an input | | SCK1 | |
| P23 | | specified by means of software. | | STB/TxD1 | |
| P24 | | | | BUSY/RxD1 | |
| P25 | | | | SI0/SB0 [/SDA0] | |
| P26 | | | | SO0/SB1 [/SDA1] | |
| P27 | | | | SCK0 [/SCL] | |
| P30 | I/O | Port 3 | | Input | TO0 |
| P31 | | 8-bit input/output port | cified in 1 bit units | | TO1 |
| P32 | | Input/output can be specified in 1-bit units. When used as an input port, an on-chip pull-up resistor can be specified | | | TO2 |
| P33 | | by means of software. | | TI1 | |
| P34 | | | | | TI2 |
| P35 | | | | | PCL |
| P36 | | | | | BUZ |
| P37 | | | | | - |
| P40 to P47 | I/O | 1 | port, an on-chip pull-up resistor can be oftware. The test input flag (KRIF) is set to 1 | Input | AD0 to AD7 |

Notes 1. When using the P07/XT1 pins as an input port, set bit 6 (FRC) of the processor clock control register (PCC) to 1. Do not use the on-chip feedback resistor of the subsystem clock oscillator.

2. When using the P10/ANI0 to P17/ANI7 pins as the A/D converter analog input pins, set port 1 to the input mode. At this time, on-chip pull-up resistors are automatically disconnected.

Remark []: μ PD78F0058Y only.

4.1 Port Pins (2/2)

| Pin Name | I/O | | Function | After Reset | Alternate Function |
|--------------|-----|---|--|----------------|-----------------------|
| P50 to P57 | I/O | Port 5 8-bit input/output port LEDs can be driven directly. Input/output can be specified When used as an input port, a means of software. | in 1-bit units. In on-chip pull-up resistor can be specified by | Input | A8 to A15 |
| P60 | I/O | Port 6 | N-ch open-drain input/output port | Input | - |
| P61 | | 8-bit input/outport port Input/output can be specified | LEDs can be driven directly. | | |
| P62 | | in 1-bit units. | | | |
| P63 | | | | | |
| P64 | | | When used as an input port, an on-chip | | RD |
| P65 | | pull-up resistor ca of software. | pull-up resistor can be specified by means of software. | | WR |
| P66 | | | | | WAIT |
| P67 | | | | | ASTB |
| P70 | I/O | Port 7 | Input | SI2/RxD0 | |
| P71 | | 3-bit input/output port | | | SO2/TxD0 |
| P72 | | Input/output can be specified in 1-bit units. When used as an input port, an on-chip pull-up resistor can be specified by means of software. | | SCK2/ASCK | |
| P120 to P127 | I/O | Port 12 8-bit input/output port Input/output can be specified When used as an input port, means of software. | in 1-bit units. on-chip pull-up resistor can be specified by | Input | RTP0 to RTP7 |
| P130, P131 | I/O | Port 13 2-bit input/output port Input/output can be specified When used as an input port, a means of software. | in 1-bit units. In on-chip pull-up resistor can be specified by | Input | ANO0, ANO1 |



4.2 Non-Port Pins (1/2)

| Pin Name | I/O | Function | After Reset | Alternate Function |
|--------------|--------|---|------------------|-----------------------|
| INTP0 | Input | External interrupt request input for which the valid edge (rising edge, | | P00/TI00 |
| INTP1 | | falling edge, or both rising edge and falling edges) can be specified. | | P01/TI01 |
| INTP2 | | | | P02 |
| INTP3 | | | | P03 |
| INTP4 | | | | P04 |
| INTP5 | | | | P05 |
| SIO | Input | Serial interface serial data input | Input | P25/SB0 [/SDA0] |
| SI1 | | | P20 | |
| SI2 | | | | P70/RxD |
| SO0 | Output | Serial interface serial data output | Input | P26/SB1 [/SDA1] |
| SO1 | | | | P21 |
| SO2 | | | | P71/TxD |
| SB0 | I/O | Serial interface serial data input/output | Input | P25/SI0 [/SDA0] |
| SB1 | | | | P26/SO0 [/SDA1] |
| SDA0 | | μPD78F0058Y only | | P25/SI0/SB0 |
| SDA1 | | | | P26/SO0/SB1 |
| SCK0 | I/O | Serial interface serial clock input/output | Input | P27 [/SCL] |
| SCK1 | | | | P22 |
| SCK2 | | | | P72/ASCK |
| SCL | | | μPD78F0058Y only | |
| STB | Output | Serial interface automatic transmit/receive strobe output | Input | P23/TxD1 |
| BUSY | Input | Serial interface automatic transmit/receive busy input | Input | P24/RxD1 |
| RxD0 | Input | Asynchronous serial interface serial data input | Input | P70/SI2 |
| RxD1 | | | | P24/BUSY |
| TxD0 | Output | Asynchronous serial interface serial data output | Input | P71/SO2 |
| TxD1 | | | | P23/STB |
| ASCK | Input | Asynchronous serial interface serial clock input | Input | P72/SCK2 |
| TIOO | Input | External count clock input to the 16-bit timer (TM0) | Input | P00/INTP0 |
| TI01 | | Capture trigger signal input to the capture register (CR00) | | P01/INTP1 |
| TI1 | | External count clock input to the 8-bit timer (TM1) | | P33 |
| TI2 | | External count clock input to the 8-bit timer (TM2) | | P34 |
| TO0 | Output | 16-bit timer (TM0) output (also used for 14-bit PWM output) | Input | P30 |
| TO1 | | 8-bit timer (TM1) output | | P31 |
| TO2 | | 8-bit timer (TM2) output | | P32 |
| PCL | Output | Clock output (for trimming of main system clock and subsystem clock) | Input | P35 |
| BUZ | Output | Buzzer output | Input | P36 |
| RTP0 to RTP7 | Output | Real-time output port from which data is output in synchronization with a trigg | er Input | P120 to P127 |
| AD0 to AD7 | I/O | Lower address/data bus for expanding memory externally | Input | P40 to P47 |

Remark []: μ PD78F0058Y only.



4.2 Non-Port Pins (2/2)

| Pin Name | I/O | Function | After Reset | Alternate Function |
|--------------------|--------|---|----------------|-----------------------|
| A8 to A15 | Output | Higher address bus for expanding memory externally | Input | P50 to P57 |
| RD | Output | Strobe signal output for reading from external memory | Input | P64 |
| WR | | Strobe signal output for writing to external memory | | P65 |
| WAIT | Input | Wait insertion at external memory access | Input | P66 |
| ASTB | Output | Strobe output that externally latches address information output to ports 4 and 5 to access external memory. | Input | P67 |
| ANI0 to ANI7 | Input | A/D converter analog input | Input | P10 to P17 |
| ANO0, ANO1 | Output | D/A converter analog output | Input | P130, P131 |
| AV _{REF0} | Input | A/D converter reference voltage input (also used for analog power supply) | _ | _ |
| AV _{REF1} | Input | D/A converter reference voltage input | _ | - |
| AVss | - | A/D converter and D/A converter ground potential Use at the same potential as Vsso. | - | _ |
| RESET | Input | System reset input | _ | - |
| X1 | Input | Connecting crystal resonator for main system clock oscillation | - | - |
| X2 | _ | | - | _ |
| XT1 | Input | Connecting crystal resonator for subsystem clock oscillation | Input | P07 |
| XT2 | _ | | _ | - |
| V _{DD0} | _ | Port block positive power supply | - | - |
| Vsso | _ | Port block ground potential | _ | - |
| V _{DD1} | ı | Positive power supply (except for port and analog blocks) | _ | _ |
| Vss1 | _ | Ground potential (except for port and analog blocks) | _ | _ |
| VPP | - | Setting flash memory programming mode. Applying high voltage for program write/verify. Connect directly to Vsso or Vss1 in normal operation mode. | _ | - |



4.3 Pin I/O Circuits and Recommended Connection of Unused Pins

The input/output circuit type of each pin and recommended connection of unused pins are shown in Table 4-1. For the input/output circuit configuration of each type, see Figure 4-1.

Table 4-1. Input/Output Circuit Type of Each Pin (1/2)

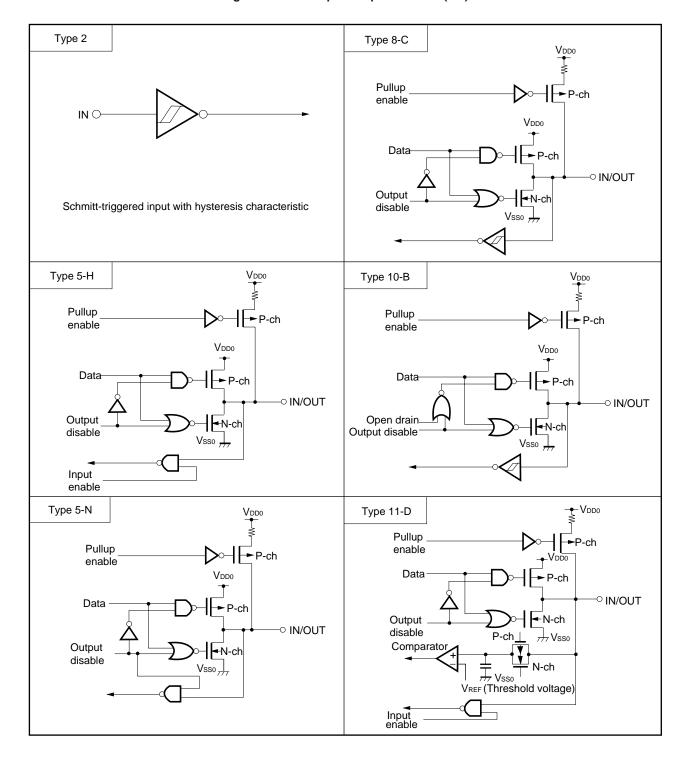
| Pin Name | Input/Output Circuit Type | I/O | Recommended Connection |
|----------------------|------------------------------|-------|---|
| P00/INTP0/TI00 | 2 | Input | Connect to Vsso. |
| P01/INTP1/TI01 | 8-C | I/O | Input : Independently connect to Vsso via a resistor. |
| P02/INTP2 | | | Output : Leave open. |
| P03/INTP3 | | | |
| P04/INTP4 | | | |
| P05/INTP5 | | | |
| P07/XT1 | 16 | Input | Connect to V _{DDO} . |
| P10/ANI0 to P17/ANI7 | 11-D | I/O | Input : Independently connect to VDDO or VSSO via a resistor. |
| P20/SI1 | 8-C | | Output: Leave open. |
| P21/S01 | 5-H | | |
| P22/SCK1 | 8-C | | |
| P23/STB/TxD1 | 5-H | | |
| P24/BUSY/RxD1 | 8-C | | |
| P25/SI0/SB0 [/SDA0] | 10-B | | |
| P26/SO0/SB1 [/SDA1] | - | | |
| P27/SCK0 [/SCL] | | | |
| P30/T00 | 5-H | | |
| P31/TO1 | | | |
| P32/TO2 | | | |
| P33/TI1 | 8-C | | |
| P34/TI2 | | | |
| P35/PCL | 5-H | | |
| P36/BUZ | | | |
| P37 | | | |
| P40/AD0 to P47/AD7 | 5-N | | Input : Independently connect to VDDO via a resistor. Output : Leave open. |
| P50/A8 to P57/A15 | 5-H | | Input : Independently connect to VDDO or VSSO via a resistor. Output : Leave open. |
| P60 to P63 | 13-K | | Input : Independently connect to VDD0 via a resistor. Output : Leave open. |
| P64/RD | 5-H | 1 | Input : Independently connect to VDD0 or VSS0 via a resistor. |
| P65/WR | 1 | | Output : Leave open. |
| P66/WAIT | 1 | | |
| P67/ASTB | 1 | | |

Remark []: μ PD78F0058Y only.

Table 4-1. Input/Output Circuit Type of Each Pin (2/2)

| Pin Name | Input/Output Circuit Type | I/O | Recommended Connection |
|---------------------------|------------------------------|-------|--|
| P70/SI2/RxD0 | 8-C | I/O | Input : Independently connect to VDD0 or VSS0 via a resistor. |
| P71/SO2/TxD0 | 5-H | _ | Output : Leave open. |
| P72/SCK2/ASCK | 8-C | | |
| P120/RTP0 to P127/RTP7 | 5-H | | |
| P130/ANO0, P131/ANO1 | 12-C | | Input : Independently connect to Vsso via a resistor. Output : Leave open. |
| RESET | 2 | Input | - |
| XT2 | 16 | _ | Leave open. |
| AV _{REF0} | _ | | Connect to Vsso. |
| AVREF1 | | | Connect to VDD0. |
| AVss | 1 | | Connect to Vsso. |
| V _{PP} | 1 | | Connect directly to Vsso or Vss1. |

Figure 4-1. Pin Input/Output Circuits (1/2)



Type 12-C Type 16 Pullup enable Feedback cut-off V_{DD0} Data -○ IN/OUT Output disable Vsso , Input enable XT1 XT2 Analog output voltage Type 13-K ⊸IN/OUT Data Output disable - N-ch VDDO $\overline{\mathsf{RD}}$ Middle-voltage input buffer

Figure 4-1. Pin Input/Output Circuits (2/2)



★ 5. MEMORY SPACE

Figure 5-1 shows the memory map of the μ PD78F0058 and 78F0058Y.

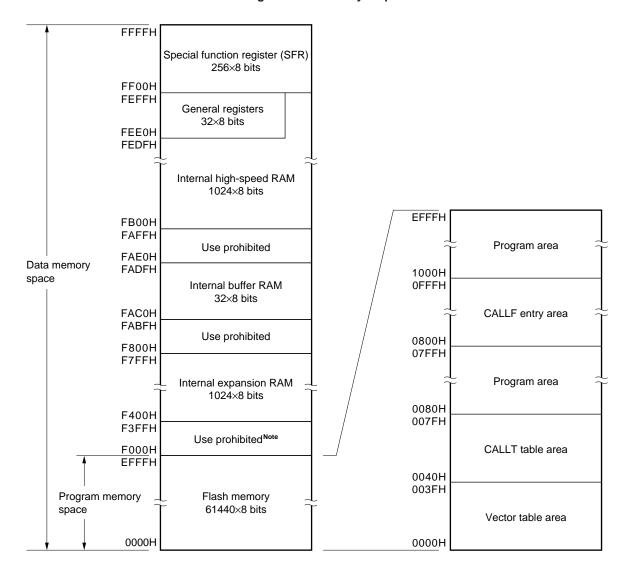


Figure 5-1. Memory Map

Note The area between F000H and F3FFH cannot be used when the flash memory size is 60 Kbytes. This area can be used by setting the flash memory size to 56 Kbytes or less with the memory size switching register (IMS).

6. FLASH MEMORY PROGRAMMING

The program memory provided in the μ PD78F0058 and 78F0058Y is flash memory.

Writing to a flash memory can be performed without removing the memory from the target system (on-board).

★ Writing is performed connecting the dedicated flash programmer (Flashpro III (part number : FL-PR3, PG-FP3) to the host machine and the target system.

Remark FL-PR3 is a product of Naito Densei Machida Mfg. Co., Ltd.

6.1 Selection of Transmission Mode

Writing to a flash memory is performed using the Flashpro III with a serial transmission mode. One of the transmission mode is selected from those in Table 6-1. The selection of the transmission mode is made by using the format shown in Figure 6-1. Each transmission mode is selected by the number of VPP pulses shown in Table 6-1.

Table 6-1. List of Transmission Mode

| Transmission Mode | Channels | Pin | V _{PP} Pulses |
|------------------------------|----------|-------------------------------------|------------------------|
| 3-wire serial I/O | 3 | P27/SCK0 [/SCL] | 0 |
| | | P26/SO0/SB1 [/SDA1] | |
| | | P25/SI0/SB0 [/SDA0] | |
| | | P22/ SCK1 | 1 |
| | | P21/SO1 | |
| | | P20/SI1 | |
| | | P72/SCK2/ASCK | 2 |
| | | P71/SO2/TxD0 | |
| | | P70/SI1/RxD0 | |
| UART | 2 | P71/SO2/TxD0 | 8 |
| | | P70/SI2/RxD0 | |
| | | P23/TxD1 | 9 |
| | | P24/RxD1 | |
| Pseudo 3-wire serial I/ONote | 1 | P32/TO2 (serial clock input/output) | 12 |
| | | P31/TO1 (serial data output) | |
| | | P30/T00 (serial data input) | |

Note Serial transmission is performed by controlling the port using software.

Caution Select a communication mode always using the number of VPP pulses shown in Table 6-1.

Remark []: μ PD78F0058Y only.

10 V
VPP VDD
VSS 1 2 n

Figure 6-1. Format of Transmission Mode Selection

★ 6.2 Function of Flash Memory Programming

Vss

Operations such as writing to a flash memory are performed by various command/data transmission and reception operations according to the selected transmission mode. Table 6-2 shows major functions of flash memory programming.

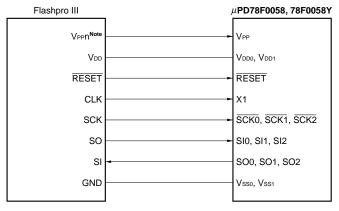
Table 6-2. Major Functions of Flash Memory Programming

| Functions | Descriptions |
|-------------------|---|
| Batch delete | Deletes the entire memory contents. |
| Batch blank check | Checks the deletion status of the entire memory. |
| Data write | Performs write to the flash memory based on the write start address and the number of data to be written (number of bytes). |
| Batch verify | Compares the entire memory contents with the input data. |

★ 6.3 Connection of Flashpro III

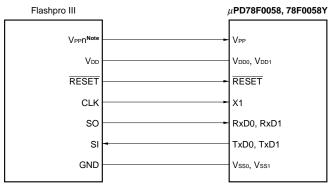
The connection of the Flashpro III and the μ PD78F0058 and 78F0058Y differs according to the transmission mode (3-wire serial I/O, UART, pseudo 3-wire). The connection for each transmission mode is shown in Figures 6-2 to 6-4.

Figure 6-2. Connection of Flashpro III for 3-wire Serial I/O Mode



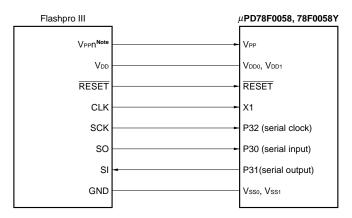
Note n = 1, 2

Figure 6-3. Connection of Flashpro III for UART Mode



Note n = 1, 2

Figure 6-4. Connection of Flashpro III for Pseudo 3-wire Serial I/O Mode



Note n = 1, 2

6.4 Example of Settings for Flashpro III (PG-FP3)

Make the following setting when writing to flash memory using Flashpro III (PG-FP3)

- <1> Load the parameter file.
- <2> Select serial mode and serial clock using the type command.
- <3> An example of the settings for the PG-FP3 is shown below.

Table 6-3. Example of Settings for PG-FP3

| Communication Mode | Example of Setting | g for PG-FP3 | Number of VPP Pulses Note 1 |
|--------------------|--------------------|----------------------------|-----------------------------|
| 3-wire serial I/O | COMM PORT | SIO-ch0/1/2 | 0/1/2 |
| | CPU CLK | On Target Board | |
| | | In Flashpro | |
| | On Target Board | 4.1943 MHz | |
| | SIO CLK | 1.0 MHz | |
| | In Flashpro | 4.0 MHz | |
| | SIO CLK | 1.0 MHz | |
| UART | COMM PORT | UART-ch0/1 | 8/9 |
| | CPU CLK | On Target Board | |
| | On Target Board | 4.1943 MHz | |
| | UART BPS | 9600 bps ^{Note 2} | |
| Pseudo 3-wire | COMM PORT | PortA | 12 |
| | CPU CLK | On Target Board | |
| | | In Flashpro | |
| | On Target Board | 4.1943 MHz | |
| | SIO CLK | 1.0 kHz | |
| | In Flashpro | 4.0 MHz | |
| | SIO CLK | 1.0 kHz | |

Notes 1. The number of VPP pulses supplied from Flashpro III when serial communication is initialized. The pins to be used for communication are determined according to the number of these pulses.

2. Select one of 9600 bps, 19200 bps, 38400 bps, or 768000 bps.

Remark COMM PORT: Selection of serial port

SIO CLK : Selection of serial clock frequency

CPU CLK : Selection of source of CPU clock to be input



★ 7. ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings ($T_A = 25^{\circ}C$)

| Parameter | Symbol | | Conditions | | Ratings | Unit |
|----------------------|---|--------------------|--------------------|---|---|------|
| Supply voltage | V _{DD} | | | | -0.3 to +6.5 | V |
| | V _{PP} | | | | -0.3 to +10.5 | V |
| | Vob Vob | V | | | | |
| | AV _{REF1} | | | -0.3 to +6.5 -0.3 to +10.5 -0.3 to Vdd +0.3 -10 -10 -15 -15 -15 -15 -15 -15 -15 -16 -17, P50-P55, -15 -15 -16 -17, P50-P55, -15 -17 -18 -19 -19 -19 -19 -19 -19 -19 -19 -19 -19 | V | |
| | AVss | | | | -0.3 to +0.3 | V |
| Input voltage | VII | P50-P57, P64-P6 | 7, P70-P72, P120-F | | -0.3 to V _{DD} + 0.3 | V |
| | Vı2 | P60-P63 | N-ch open drain | | -0.3 to +16 | V |
| Output voltage | Vo | | | | -0.3 to V _{DD} + 0.3 | V |
| Analog input voltage | Van | P10-P17 | Analog input pin | | AVss - 0.3 to AVREF0 + 0.3 | V |
| Output | Іон | Per pin | | | -0.3 to V _{DD} + 0.3 AVss - 0.3 to AV _{REF0} + 0.3 -10 7, -15 6, -15 value 30 tlue 15 | mA |
| current, high | | | i, P30-P37, P56, P | 57, P60-P67, | | mA |
| | | | | 7, P50-P55, | -15 | mA |
| Output | _{OL} Note | Per pin Peak value | | 30 | mA | |
| current, low | | | | rms value | 15 | mA |
| | | Total for P50-P55 | | Peak value | 100 | mA |
| | | | | rms value | 70 | mA |
| | | Total for P56, P5 | 7, P60-P63 | Peak value | 100 | mA |
| | | | | rms value | 70 | mA |
| | | Total for P10-P17 | , P20-P27, | Peak value | 50 | mA |
| | | P40-P47, P70-P7 | 2, P130, P131 | rms value | 20 | mA |
| | | Total for P01-P05 | , P30-P37, | Peak value | 50 | mA |
| | | P64-P67, P120-P | 127 | rms value | 20 | mA |
| Operating ambient | TA | During normal op | eration | | -40 to +85 | °C |
| temperature | | During flash mem | ory programming | | 10 to 40 | °C |
| Storage temperature | T _{stg} | | | | -65 to +125 | °C |

Note The rms value should be calculated as follows: [rms value] = [Peak value] $\times \sqrt{\text{Duty}}$

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.



Main System Clock Oscillator Characteristics (T_A = −40 to +85°C, V_{DD} = 2.7 to 5.5 V)

| Resonator | Recommended Circuit | Parameter | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|---------------------|---|--|------|------|------|------|
| Ceramic resonator | X2 X1 VPP | Oscillation frequency (fx) ^{Note 1} | V _{DD} = Oscillation voltage range | 1.0 | | 5.0 | MHz |
| | + | Oscillation stabilization time Note 2 | After V _{DD} reaches oscillation voltage range MIN. | | | 4 | ms |
| Crystal resonator | X2 X1 VPP | Oscillation frequency (fx) ^{Note 1} | | 1.0 | | 5.0 | MHz |
| | + | Oscillation | V _{DD} = 4.5 to 5.5 V | | | 10 | ms |
| | 77 | stabilization time ^{Note 2} | | | | 30 | |
| External clock | X2 X1 | X1 input frequency (fx)Note 1 | | 1.0 | | 5.0 | MHz |
| | μPD74HCU04 | X1 input high-/low-level width (txH, txL) | | 85 | | 500 | ns |

- Notes 1. Indicates only oscillator characteristics. Refer to AC Characteristics for instruction execution time.
 - 2. Time required to stabilize oscillation after reset or STOP mode release.
- Cautions 1. When using the main system clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.
 - Keep the wiring length as short as possible.
 - · Do not cross the wiring with the other signal lines.
 - . Do not route the wiring near a signal line through which a high fluctuating current flows.
 - Always make the ground point of the oscillator capacitor the same potential as Vss1.
 - Do not ground the capacitor to a ground pattern through which a high current flows.
 - Do not fetch signals from the oscillator.
 - 2. When the main system clock is stopped and the system is operating on the subsystem clock, wait until the oscillation stabilization time has been secured by the program before switching back to the main system clock.

Remark For the resonator selection and oscillator constant, customers are requested to either evaluate the oscillation themselves or apply to the resonator manufacturer for evaluation.

| Resonator | Recommended Circuit | Parameter | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|---------------------|--|--|------|--------|------|------|
| Crystal resonator | VPP XT2 XT1 | Oscillation frequency (fxt)Note 1 | | 32 | 32.768 | 35 | kHz |
| | C4= C3 = | Oscillation | $V_{DD} = 4.5 \text{ to } 5.5 \text{ V}$ | | 1.2 | 2 | S |
| | <i>m</i> | stabilization time ^{Note 2} | | | | 10 | |
| External clock | XT2 XT1 | XT1 input frequency (fxt)Note 1 | | 32 | | 100 | kHz |
| | μPD74HCU04Δ | XT1 input high-/low-level width (txth, txtl) | | 5 | | 15 | μs |

- Notes 1. Indicates only oscillator characteristics. Refer to AC Characteristics for instruction execution time.
 - 2. Time required to stabilize oscillation after VDD reaches oscillation voltage range MIN.

Cautions 1. When using the subsystem clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- · Keep the wiring length as short as possible.
- · Do not cross the wiring with the other signal lines.
- Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor the same potential as Vss1.
- Do not ground the capacitor to a ground pattern through which a high current flows.
- · Do not fetch signals from the oscillator.
- The subsystem clock oscillator is designed as a low-amplitude circuit for reducing current consumption, and is more prone to malfunction due to noise than the main system clock oscillator. Particular care is therefore required with the wiring method when the subsystem clock is used.

Remark For the resonator selection and oscillator constant, customers are requested to either evaluate the oscillation themselves or apply to the resonator manufacturer for evaluation.

Capacitance (TA = 25°C, VDD = Vss = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--------------------|--------|--|---|------|------|------|------|
| Input capacitance | Cin | f = 1 MHz Unmeasured pins returned to | 0 V. | | | 15 | pF |
| I/O capacitance | Сю | f = 1 MHz Unmeasured pins returned to 0 V. | P01-P05, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P64-P67, P70-P72, P120-P127, P130, P131 | | | 15 | pF |
| | | | P60-P63 | | | 20 | pF |

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of port pins.



DC Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|------------------------|------------------|---|---|-----------------------|------|--------------------|------|
| Input voltage, high | V _{IH1} | P10-P17, P21, P23, P30-P32, P35-P37, P40-P47, P50-P57, P64-P67, P71, P120-P127, P130, P131 | V _{DD} = 2.7 to 5.5 V | 0.7V _{DD} | | V _{DD} | V |
| | V _{IH2} | P00-P05, P20, P22, P24-P27, P33, P34, P70, P72, RESET | V _{DD} = 2.7 to 5.5 V | 0.8V _{DD} | | V _{DD} | V |
| | VIH3 | P60-P63 (N-ch open drain) | V _{DD} = 2.7 to 5.5 V | 0.7V _{DD} | | 15 | V |
| | V _{IH4} | X1, X2 | V _{DD} = 2.7 to 5.5 V | V _{DD} - 0.5 | | V _{DD} | V |
| | V _{IH5} | XT1/P07, XT2 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 0.8V _{DD} | | V _{DD} | V |
| | | | 2.7 V ≤ V _{DD} < 4.5 V | 0.9V _{DD} | | V _{DD} | V |
| Input voltage, low | VIL1 | P10-P17, P21, P23, P30-P32, P35-P37, P40-P47, P50-P57, P64-P67, P71, P120-P127, P130, P131 | V _{DD} = 2.7 to 5.5 V | 0 | | 0.3V _{DD} | V |
| | VIL2 | P00-P05, P20, P22, P24-P27, P33, P34, P70, P72, RESET | V _{DD} = 2.7 to 5.5 V | 0 | | 0.2V _{DD} | V |
| | V _{IL3} | P60-P63 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 0 | | 0.3V _{DD} | V |
| | | | 2.7 V ≤ V _{DD} < 4.5 V | 0 | | 0.2V _{DD} | V |
| | VIL4 | X1, X2 | V _{DD} = 2.7 to 5.5 V | 0 | | 0.4 | V |
| | VIL5 | XT1/P07, XT2 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 0 | | 0.2V _{DD} | V |
| | | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 0 | | 0.1V _{DD} | V |
| Output voltage, | Vон | $V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ IoH} = -1 \text{ mA}$ | | V _{DD} - 1.0 | | | V |
| high | | Iон = −100 μA | | V _{DD} - 0.5 | | | V |
| Output voltage, low | Vol1 | P50-P57, P60-P63 | $V_{DD} = 4.5 \text{ to } 5.5 \text{ V},$ $I_{OL} = 15 \text{ mA}$ | | 0.4 | 2.0 | V |
| | | P01-P05, P10-P17, P20-P27, P30-P37, P40-P47, P64-P67, P70-P72, P120-P127, P130, P131 | V _{DD} = 4.5 to 5.5 V, I _{OL} = 1.6 mA | | | 0.4 | V |
| | V _{OL2} | SB0, SB1, SCK0 | $V_{DD} = 4.5 \text{ to } 5.5 \text{ V},$ open drain, pulled-up (R = 1 k Ω) | | | 0.2V _{DD} | V |
| | V _{OL3} | IoL = 400 μA | | | | 0.5 | V |

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of port pins.



DC Characteristics (T_A = -40 to +85°C, V_{DD} = 2.7 to 5.5 V)

| Parameter | Symbol | | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|-------------------|------------|---|------|------|----------|------|
| Input leakage current, high | Ішні | VIN = VDD | P00-P05, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P72, P120-P127, P130, P131, RESET | | | 3 | μΑ |
| | I _{LIH2} | | X1, X2, XT1/P07, XT2 | | | 20 | μΑ |
| | Ілнз | Vin = 15 V | P60 to P63 | | | 80 | μΑ |
| Input leakage current, low | ILIL1 | Vin = 0 V | P00-P05, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P64-P67, P70-P72, P120-P127, P130, P131, RESET | | | -3 | μΑ |
| | I _{LIL2} | | X1, X2, XT1/P07, XT2 | | | -20 | μΑ |
| | ILIL3 | | P60-P63 | | | _3Note 1 | μΑ |
| Output leakage current, high | Ісон | Vout = Vdd | | | | 3 | μΑ |
| Output leakage current, low | ILOL | Vout = 0 V | | | | -3 | μΑ |
| Software pull-up resistor Note 2 | R | | -P05, P10-P17, P20-P27, P30-P37, P57, P64-P67, P70-P72, P120-P127, | 15 | 30 | 90 | kΩ |

Notes 1. A low-level input leakage current of $-200~\mu\text{A}$ (MAX.) flows only for 1.5 clocks (without wait) after a read instruction has been executed to port 6 (P6) or port mode register 6 (PM6). At times other than this 1.5-clock interval, a $-3~\mu\text{A}$ (MAX.) current flows.

2. Software pull-up resistor can only be used within the range V_{DD} = 2.7 to 5.5 V.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of port pins.



DC Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$)

| Parameter | Symbol | Conditio | MIN. | TYP. | MAX. | Unit | |
|--|-------------------------|--|---|------|------|------|----|
| IDD2 IDD2 IDD2 IDD3 IDD4 IDD5 Note | I _{DD1} Note 5 | 5 5.0 MHz crystal oscillation operating mode (fxx = 2.5 MHz) ^{Note 3} | V _{DD} = 5.0 V ±10% ^{Note 1} | | 6.2 | 12.5 | mA |
| | | | $V_{DD} = 3.0 \text{ V} \pm 10\%^{\text{Note 2}}$ | | 1.3 | 3.1 | mA |
| | | 5.0 MHz crystal oscillation operating mode | V _{DD} = 5.0 V ±10% ^{Note 1} | | 13.1 | 25.7 | mA |
| | | (fxx = 5.0 MHz) ^{Note 4} | V _{DD} = 3.0 V ±10% ^{Note 2} | | 2.1 | 4.9 | mA |
| | I _{DD2} | 5.0 MHz crystal oscillation HALT mode (fxx = 2.5 MHz)Note 3 | V _{DD} = 5.0 V ±10% | | | | |
| | | | Peripheral functions operating | | | 5.6 | mA |
| | | | Peripheral functions not operating | | 1.0 | 2.8 | mA |
| | | | V _{DD} = 3.0 V ±10% | | | | |
| | | | Peripheral functions operating | | | 2.9 | mA |
| | | | Peripheral functions not operating | | 0.44 | 1.1 | mA |
| | | 5.0 MHz crystal oscillation HALT mode (fxx = 5.0 MHz)Note 4 | VDD = 5.0 V ±10% | | | | |
| | | | Peripheral functions operating | | | 8.4 | mA |
| | | | Peripheral functions not operating | | 1.3 | 3.1 | mA |
| | | | V _{DD} = 3.0 V ±10% | | | | |
| | | | Peripheral functions operating | | | 4.5 | mA |
| | | | Peripheral functions not operating | | 0.6 | 1.5 | mA |
| | I _{DD3} Note 5 | 32.768 kHz crystal oscillation operating mode ^{Note 6} | V _{DD} = 5.0 V ±10% | | 110 | 220 | μΑ |
| | | | V _{DD} = 3.0 V ±10% | | 86 | 172 | μΑ |
| | _{DD4} Note 5 | 32.768 kHz crystal oscillation | V _{DD} = 5.0 V ±10% | | 22.5 | 45 | μΑ |
| | | HALT mode ^{Note 6} | V _{DD} = 3.0 V ±10% | | 3.2 | 6.4 | μΑ |
| | I _{DD5} Note 5 | XT1 = V _{DD} STOP mode When feedback resistor is used | V _{DD} = 5.0 V ±10% | | 1.0 | 30 | μΑ |
| | | | V _{DD} = 3.0 V ±10% | | 0.5 | 10 | μΑ |
| | _{DD6} Note 5 | XT1 = V _{DD} | V _{DD} = 5.0 V ±10% | | 0.1 | 30 | μΑ |
| | | STOP mode When feedback resistor is not used | V _{DD} = 3.0 V ±10% | | 0.05 | 10 | μΑ |

Notes 1. High-speed mode operation (when the processor clock control register (PCC) is set to 00H).

- 2. Low-speed mode operation (when PCC is set to 04H).
- 3. Operation with main system clock fxx = fx/2 (when the oscillation mode select register (OSMS) is set to 00H)
- **4.** Operation with main system clock fxx = fx (when OSMS is set to 01H)
- **5.** Refers to the current flowing to the V_{DD0} and V_{DD1} pins. The current flowing to the A/D converter, D/A converter, and on-chip pull-up resistor is not included.
- **6.** When the main system clock operation is stopped.



AC Characteristics

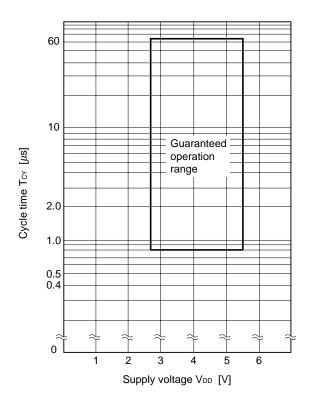
(1) Basic operation (T_A = -40 to +85°C, V_{DD} = 2.7 to 5.5 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit | |
|---------------------------------|------------------|--|---|--|------|------|-----|
| Cycle time (Min. instruction | Тсү | Operating with main system clock (fxx = 2.5 MHz)Note 1 | V _{DD} = 2.7 to 5.5 V | 0.8 | | 64 | μs |
| execution time) | | Operating with main system | 3.5 V ≤ V _{DD} ≤ 5.5 V | 0.4 | | 32 | μs |
| | | clock (fxx = 5.0 MHz)Note 2 | 2.7 V ≤ V _{DD} < 3.5 V | 0.8 | | 32 | μs |
| | | Operating with subsystem clock | 40Note 3 | 122 | 125 | μs | |
| TI00 input high-/ | t TIH00 | 3.5 V ≤ V _{DD} ≤ 5.5 V | 2/f _{sam} + 0.1 ^{Note 4} | | | μs | |
| low-level width | t TIL00 | 2.7 V ≤ V _{DD} < 3.5 V | 2/f _{sam} + 0.2 ^{Note 4} | | | μs | |
| TI01 input high-/ | t TIH01 | V _{DD} = 2.7 to 5.5 V | | 10 | | | μs |
| low-level width | t TIL01 | | | | | | |
| TI1, TI2 input | f _{Tl1} | V _{DD} = 4.5 to 5.5 V | 0 | | 4 | MHz | |
| frequency | | | | 0 | | 275 | kHz |
| TI1, TI2 input | t тін1 | V _{DD} = 4.5 to 5.5 V | 100 | | | ns | |
| high-/low-level width | tTIL1 | | | 1.8 | | | μs |
| Interrupt request | tinth | INTP0 | $3.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 2/f _{sam} + 0.1 Note 4 | | | μs |
| input high-/ | tintl | | 2.7 V ≤ V _{DD} < 3.5 V | 2/f _{sam} + 0.2 ^{Note 4} | | | μs |
| low-level width | | INTP1-INTP5, P40-P47 | V _{DD} = 2.7 to 5.5 V | 10 | | | μs |
| RESET low- level width | trsl | V _{DD} = 2.7 to 5.5 V | | 10 | | | μs |

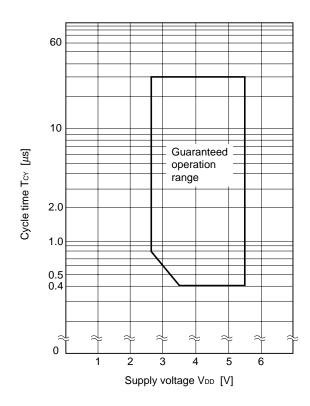
Notes 1. Operation with main system clock fxx = fx/2 (when the oscillation mode select register (OSMS) is set to 00H)

- **2.** Operation with main system clock fxx = fx (when OSMS is set to 01H)
- 3. Value when external clock is used. When a crystal resonator is used, it is 114 μ s (MIN.)
- **4.** Selection of $f_{sam} = f_{xx}/2^N$, $f_{xx}/32$, $f_{xx}/64$, and $f_{xx}/128$ is possible with bits 0 and 1 (SCS0, SCS1) of the sampling clock select register (SCS) (when N= 0 to 4).

Tcy vs. V_{DD} (@fxx = fx/2 main system clock operation)



Tcy vs. V_{DD} (@fxx = fx main system clock operation)





(2) Read/write operation

(a) When MCS = 1, PCC2 to PCC0 = 000B ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 3.5 \text{ to } 5.5 \text{ V}$)

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|--|----------------|------------|----------------------|----------------------|------|
| ASTB high-level width | tasth | | 0.85tcy - 50 | | ns |
| Address setup time | tads | | 0.85tcy - 50 | | ns |
| Address hold time | tadh | | 50 | | ns |
| Data input time from address | tADD1 | | | (2.85 + 2n)tcy - 80 | ns |
| | tADD2 | | | (4 + 2n)tcy - 100 | ns |
| Data input time from $\overline{RD} \downarrow$ | trdd1 | | | (2 + 2n)tcy - 100 | ns |
| | trdd2 | | | (2.85 + 2n)tcy - 100 | ns |
| Read data hold time | trdh | | 0 | | ns |
| RD low-level width | trdL1 | | (2 + 2n)tcy - 60 | | ns |
| | tRDL2 | | (2.85 + 2n)tcy - 60 | | ns |
| $\overline{\text{WAIT}} \downarrow \text{ input time from } \overline{\text{RD}} \downarrow$ | trdwt1 | | | 0.85tcy - 50 | ns |
| | trdwt2 | | | 2tcy - 60 | ns |
| $\overline{\mathrm{WAIT}}{\downarrow}$ input time from $\overline{\mathrm{WR}}{\downarrow}$ | twrwt | | | 2tcy - 60 | ns |
| WAIT low-level width | twTL | | (1.15 + 2n)tcy | (2 + 2n)tcy | ns |
| Write data setup time | twos | | (2.85 + 2n)tcy - 100 | | ns |
| Write data hold time | twdh | | 20 | | ns |
| WR low-level width | twrL | | (2.85 + 2n)tcy - 60 | | ns |
| $\overline{\text{RD}} \downarrow \text{ delay time from ASTB} \downarrow$ | tastrd | | 25 | | ns |
| $\overline{\mathrm{WR}} \!\!\downarrow \mathrm{delay}$ time from ASTB $\!\!\downarrow$ | tastwr | | 0.85tcy + 20 | | ns |
| ASTB↑ delay time from RD↑ at external fetch | t rdast | | 0.85tcy - 10 | 1.15tcy + 20 | ns |
| Address hold time from RD↑ at external fetch | t RDADH | | 0.85tcy - 50 | 1.15tcy + 50 | ns |
| Write data output time from $\overline{\text{RD}} \uparrow$ | trowd | | 40 | | ns |
| Write data output time from $\overline{\mathrm{WR}} \!\!\downarrow$ | twrwd | | 0 | 50 | ns |
| Address hold time from $\overline{\mathrm{WR}} \!\!\uparrow$ | twradh | | 0.85tcy | 1.15tcy + 40 | ns |
| RD↑ delay time from WAIT↑ | twtrd | | 1.15tcy + 40 | 3.15tcy + 40 | ns |
| WR↑ delay time from WAIT↑ | twrwr | | 1.15tcy + 30 | 3.15tcy + 30 | ns |

- Remarks 1. MCS: Bit 0 of the oscillation mode select register (OSMS)
 - 2. PCC2 to PCC0: Bits 2 to 0 of the processor clock control register (PCC)
 - 3. tcy = Tcy/4
 - 4. n indicates the number of waits.



(b) When MCS = 0 or PCC2 to PCC0 \neq 000B (TA = -40 to +85°C, VDD = 2.7 to 5.5 V)

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|--|-------------------|------------|--------------------|--------------------|------|
| ASTB high-level width | t asth | | tcy - 80 | | ns |
| Address setup time | tads | | tcy - 80 | | ns |
| Address hold time | tadh | | 0.4tcy - 10 | | ns |
| Data input time from address | t _{ADD1} | | | (3 + 2n)tcy - 160 | ns |
| | tADD2 | | | (4 + 2n)tcy - 200 | ns |
| Data input time from RD↓ | tRDD1 | | | (1.4 + 2n)tcy - 70 | ns |
| | tRDD2 | | | (2.4 + 2n)tcy - 70 | ns |
| Read data hold time | t RDH | | 0 | | ns |
| RD low-level width | tRDL1 | | (1.4 + 2n)tcy - 20 | | ns |
| | tRDL2 | | (2.4 + 2n)tcy - 20 | | ns |
| WAIT↓ input time from RD↓ | trdwT1 | | | tcy - 100 | ns |
| | trdwt2 | | | 2tcy - 100 | ns |
| WAIT↓ input time from WR↓ | twrwt | | | 2tcy - 100 | ns |
| WAIT low-level width | twTL | | (1 + 2n)tcy | (2 + 2n)tcy | ns |
| Write data setup time | twos | | (2.4 + 2n)tcy - 60 | | ns |
| Write data hold time | twoн | | 20 | | ns |
| WR low-level width | twrL | | (2.4 + 2n)tcy - 20 | | ns |
| RD↓ delay time from ASTB↓ | tastrd | | 0.4tcy - 30 | | ns |
| WR↓ delay time from ASTB↓ | tastwr | | 1.4tcy - 30 | | ns |
| ASTB↑ delay time from RD↑ at external fetch | trdast | | tcy - 10 | tcy + 20 | ns |
| Address hold time from RD↑ at external fetch | trdadh | | tcy - 50 | tcy + 50 | ns |
| Write data output time from RD↑ | trdwd | | 0.4tcy - 20 | | ns |
| Write data output time from WR↓ | twrwd | | 0 | 60 | ns |
| Address hold time from WR↑ | twradh | | tcy | tcy + 60 | ns |
| RD↑ delay time from WAIT↑ | twtrd | | 0.6tcy + 180 | 2.6tcy + 180 | ns |
| WR↑ delay time from WAIT↑ | twrwr | | 0.6tcy + 120 | 2.6tcy + 120 | ns |

- Remarks 1. MCS: Bit 0 of the oscillation mode select register (OSMS)
 - 2. PCC2 to PCC0: Bits 2 to 0 of the processor clock control register (PCC)
 - 3. tcy = Tcy/4
 - 4. n indicates the number of waits.



(3) Serial interface (T_A = -40 to +85°C, V_{DD} = 2.7 to 5.5 V)

(a) Serial interface channel 0

(i) 3-wire serial I/O mode (SCK0... Internal clock output)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|------------|--|---------------|------|------|------|
| SCK0 cycle time | tkcy1 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 800 | | | ns |
| | , | 2.7 V ≤ V _{DD} < 4.5 V | 1,600 | | | ns |
| SCK0 high-/low-level | tkH1, tkL1 | V _{DD} = 4.5 to 5.5 V | tkcy1/2 - 50 | | | ns |
| width | | | tkcy1/2 - 100 | | | ns |
| SI0 setup time | tsık1 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 100 | | | ns |
| (to SCK0↑) | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 150 | | | ns |
| SI0 hold time (from SCK0↑) | tksi1 | | 400 | | | ns |
| SO0 output delay time from SCK0↓ | tkso1 | C = 100 pF ^{Note} | | | 300 | ns |

Note C is the load capacitance of the $\overline{SCK0}$ and SO0 output lines.

(ii) 3-wire serial I/O mode (SCK0... External clock input)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|------------|--|-------|------|-------|------|
| SCK0 cycle time | tkcy2 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 800 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 1,600 | | | ns |
| SCK0 high-/low-level | tкн2, tкL2 | 4.5 V ≤ V _{DD} ≤ 5.5 V | 400 | | | ns |
| width | | 2.7 V ≤ V _{DD} < 4.5 V | 800 | | | ns |
| SI0 setup time (to SCK0↑) | tsıк2 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 100 | | | ns |
| SI0 hold time (from SCK0↑) | tĸsı2 | | 400 | | | ns |
| SO0 output delay time from SCK0↓ | tkso2 | C = 100 pF ^{Note} | | | 300 | ns |
| SCK0 rise/fall time | tr2, tr2 | When using external device expansion function | | | 160 | ns |
| | | When not using external device expansion function | | | 1,000 | ns |

Note C is the load capacitance of the SO0 output line.



(iii) 2-wire serial I/O mode (SCK0... Internal clock output)

| Parameter | Symbol | Co | nditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------------|--------|----------------------------|---|---------------|------|------|------|
| SCK0 cycle time | tксүз | $R = 1 k\Omega$, | $2.7 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 1,600 | | | ns |
| SCK0 high-level width | tкнз | C = 100 pF ^{Note} | V _{DD} = 2.7 to 5.5 V | tксүз/2 – 160 | | | ns |
| SCK0 low-level width | tкLз | | V _{DD} = 4.5 to 5.5 V | tксүз/2 — 50 | | | ns |
| | | | | tксүз/2 – 100 | | | ns |
| SB0, SB1 setup time | tsıкз | | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 300 | | | ns |
| (to SCK0↑) | | | 2.7 V ≤ V _{DD} < 4.5 V | 350 | | | ns |
| SB0, SB1 hold time (from SCK0↑) | tksi3 | | | 600 | | | ns |
| SB0, SB1 output delay time from SCK0↓ | tкsоз | | | 0 | | 300 | ns |

Note R and C are the load resistance and load capacitance of the $\overline{SCK0}$, SB0, and SB1 output lines.

(iv) 2-wire serial I/O mode (SCK0... External clock input)

| Parameter | Symbol | Со | nditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------|------------------|--------------------------------|--|---------|------|-------|------|
| SCK0 cycle time | tkcy4 | 2.7 V ≤ V _{DD} ≤ 5 | 5.5 V | 1,600 | | | ns |
| SCK0 high-level width | t _{KH4} | 2.7 V ≤ V _{DD} ≤ 5 | i.5 V | 650 | | | ns |
| SCK0 low-level width | t _{KL4} | 2.7 V ≤ V _{DD} ≤ 5 | 5.5 V | 800 | | | ns |
| SB0, SB1 setup time (to SCK0↑) | tsık4 | $V_{DD} = 2.7 \text{ to } 5.5$ | 5 V | 100 | | | ns |
| SB0, SB1 hold time (from SCK0↑) | tksi4 | | | tkcy4/2 | | | ns |
| SB0, SB1 output delay | t ks04 | $R = 1 k\Omega$, | $4.5~\textrm{V} \leq \textrm{V}_\textrm{DD} \leq 5.5~\textrm{V}$ | 0 | | 300 | ns |
| time from SCK0↓ | | C = 100 pF ^{Note} | $2.7 \text{ V} \le \text{V}_{DD} < 4.5 \text{ V}$ | 0 | | 500 | ns |
| SCK0 rise/fall time | tr4, tf4 | When using ex expansion fund | | | | 160 | ns |
| | | When not using expansion fund | g external device | | | 1,000 | ns |

Note R and C are the load resistance and load capacitance of the SB0 and SB1 output lines.



(v) SBI mode ($\overline{\text{SCK0}}$... Internal clock output) (μ PD78F0058 only)

| Parameter | Symbol | Cor | nditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------|------------|---|--------------------------------|---------------|------|-------|------|
| SCK0 cycle time | tkcy5 | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5$ | .5 V | 800 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4 | .5 V | 3,200 | | | ns |
| SCK0 high-/low-level | tkH5, tkL5 | 4.5 V ≤ V _{DD} ≤ 5 | .5 V | tkcy5/2 - 50 | | | ns |
| width | | 2.7 V ≤ V _{DD} < 4 | .5 V | tксү5/2 – 150 | | | ns |
| SB0, SB1 setup time | tsik5 | 4.5 V ≤ V _{DD} ≤ 5 | .5 V | 100 | | | ns |
| (to SCK0↑) | | 2.7 V ≤ V _{DD} < 4 | .5 V | 300 | | | ns |
| SB0, SB1 hold time (from SCK0↑) | tksi5 | | | tксү5/2 | | | ns |
| SB0, SB1 output delay | tkso5 | $R = 1 k\Omega$, | V _{DD} = 4.5 to 5.5 V | 0 | | 250 | ns |
| time from SCK0↓ | | C = 100 pF ^{Note} | | 0 | | 1,000 | ns |
| SB0, SB1↓ from SCK0↑ | tкsв | | | tkcy5 | | | ns |
| SCK0↓ from SB0, SB1↓ | tsвк | | | tkcy5 | | | ns |
| SB0, SB1 high-level width | tsвн | | | tkcy5 | | | ns |
| SB0, SB1 low-level width | tsbl | | | tkcy5 | | | ns |

Note R and C are the load resistance and load capacitance of the SCKO, SBO, and SB1 output lines.

(vi) SBI mode (SCK0... External clock input) (μPD78F0058 only)

| Parameter | Symbol | Cor | nditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------|----------------------------|---|--|---------|------|-------|------|
| SCK0 cycle time | t ксу6 | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5$ | .5 V | 800 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4 | .5 V | 3,200 | | | ns |
| SCK0 high-/low-level | t кн6, t кL6 | 4.5 V ≤ V _{DD} ≤ 5 | .5 V | 400 | | | ns |
| width | | 2.7 V ≤ V _{DD} < 4 | .5 V | 1,600 | | | ns |
| SB0, SB1 setup time | tsik6 | 4.5 V ≤ V _{DD} ≤ 5 | 4.5 V ≤ V _{DD} ≤ 5.5 V | | | | ns |
| (to SCK0 ↑) | | 2.7 V ≤ V _{DD} < 4 | .5 V | 300 | | | ns |
| SB0, SB1 hold time (from SCK0↑) | tksi6 | | | tксү6/2 | | | ns |
| SB0, SB1 output delay | tkso6 | $R = 1 k\Omega$, | V _{DD} = 4.5 to 5.5 V | 0 | | 300 | ns |
| time from SCK0↓ | | C = 100 pF ^{Note} | | 0 | | 1,000 | ns |
| SB0, SB1↓ from SCK0↑ | tksb | | | tксу6 | | | ns |
| SCK0↓ from SB0, SB1↓ | tsвк | | | tkcy6 | | | ns |
| SB0, SB1 high-level width | tsвн | | | tkcy6 | | | ns |
| SB0, SB1 low-level width | tsbl | | | tксу6 | | | ns |
| SCK0 rise/fall time | tre, tre | _ | When using external device expansion function When not using external device expansion function | | | 160 | ns |
| | | _ | | | | 1,000 | ns |

Note R and C are the load resistance and load capacitance of the SB0 and SB1 output lines.



(vii) I²C bus mode (SCL... Internal clock output) (μ PD78F0058Y only)

| Parameter | Symbol | Со | nditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------|------------------|----------------------------|--|-------------|------|------|------|
| SCL cycle time | t ксү7 | $R = 1 k\Omega$, | $2.7 \text{ V} \leq \text{V}_{DD} < 5.5 \text{ V}$ | 10 | | | μs |
| SCL high-level width | t кн7 | C = 100 pF ^{Note} | 2.7 V ≤ V _{DD} < 5.5 V | tксү7 – 160 | | | μs |
| SCL low-level width | t _{KL7} | | 4.5 V ≤ V _{DD} < 5.5 V | tксү7 — 50 | | | ns |
| | | | 2.7 V ≤ V _{DD} < 4.5 V | tксү7 — 100 | | | ns |
| SDA0, SDA1 setup time | tsık7 | | $2.7 \text{ V} \leq \text{V}_{DD} < 5.5 \text{ V}$ | 200 | | | ns |
| (to SCL↑) | | | | | | | |
| SDA0, SDA1 hold time | tksi7 | | | 0 | | | ns |
| (from SCL↓) | | | | | | | |
| SDA0, SDA1 output delay | t кso7 | | 4.5 V ≤ V _{DD} < 5.5 V | 0 | | 300 | ns |
| time from SCL↓ | | | | 0 | | 500 | ns |
| SDA0, SDA1↓ from SCL↑ | | | | 200 | | | ns |
| or SDA0, SDA1↑ from SCL↑ | | | | | | | |
| SCL↓ from SDA0, SDA1↓ | tsвк | | | 400 | | | ns |
| SDA0, SDA1 high-level width | tsвн | | | 500 | | | ns |

Note R and C are the load resistance and load capacitance of the SCL, SDA0, and SDA1 output lines.

(viii) I²C bus mode (SCL... External clock input) (µPD78F0058Y only)

| Parameter | Symbol | Со | nditions | MIN. | TYP. | MAX. | Unit |
|--|---------------|-------------------|---------------------------------|------|------|------|------|
| SCL cycle time | t ксү8 | | | 1 | | | μs |
| SCL high-level width | t кн8 | | | 400 | | | ns |
| SDA0, SDA1 setup time (to SCL [↑]) | tsik8 | | | 200 | | | ns |
| SDA0, SDA1 hold time (from SCL↓) | tksi8 | | | 0 | | | ns |
| SDA0, SDA1 output delay | tkso8 | $R = 1 k\Omega$, | 4.5 V ≤ V _{DD} < 5.5 V | 0 | | 300 | ns |
| time from SCL↓ | | C = 100 pFNote | | 0 | | 500 | ns |
| SDA0, SDA1↓ from SCL↑ or SDA0, SDA1↑ from SCL↑ | | | | 200 | | | ns |
| SCL↓ from SDA0, SDA1↓ | tsBK | | | 400 | | | ns |
| SDA0, SDA1 high-level width | tsвн | | | 500 | | | ns |

Note R and C are the load resistance and load capacitance of the SDA0 and SDA1 output lines.

(b) Serial interface channel 1

(i) 3-wire serial I/O mode (SCK1...Internal clock output)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|---------------|--|---------------|------|------|------|
| SCK1 cycle time | tkcy9 | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 800 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 1,600 | | | ns |
| SCK1 high-/low-level width | tkH9, tkL9 | V _{DD} = 4.5 to 5.5 V | tксү9/2 - 50 | | | ns |
| | | | tксү9/2 – 100 | | | ns |
| SI1 setup time (to SCK1↑) | tsik9 | $4.5~\textrm{V} \leq \textrm{V}_\textrm{DD} \leq 5.5~\textrm{V}$ | 100 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 150 | | | ns |
| SI1 hold time (from SCK1↑) | tksi9 | | 400 | | | ns |
| SO1 output delay time from $\overline{\text{SCK1}} \downarrow$ | t KSO9 | C = 100 pF ^{Note} | | | 300 | ns |

Note C is the load capacitance of the $\overline{\text{SCK1}}$ and SO1 output lines.

(ii) 3-wire serial I/O mode (SCK1...External clock input)

| Parameter | Symbol | Cor | nditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|-------------------------------------|--|---------------------------------|-------|------|-------|------|
| SCK1 cycle time | t KCY10 | $4.5 \text{ V} \leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | | 800 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.5 V | | 1,600 | | | ns |
| SCK1 high-/low-level width | tkH10, tkL10 | 4.5 V ≤ V _{DD} ≤ 5.5 V | | 400 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.5 | 2.7 V ≤ V _{DD} < 4.5 V | | | | ns |
| SI1 setup time (to SCK1↑) | tsik10 | V _{DD} = 2.7 to 5.5 V | | 100 | | | ns |
| SI1 hold time (from SCK1↑) | tkis10 | | | 400 | | | ns |
| SO1 output delay time from SCK1↓ | t KSO10 | C = 100 pF ^{Note} | V _{DD} = 2.7 to 5.5 V | | | 300 | ns |
| SCK1 rise/fall time | t _{R10} , t _{F10} | When using external device expansion function | | | | 160 | ns |
| | | When not using expansion function | | | | 1,000 | ns |

Note C is the load capacitance of the SO1 output line.



(iii) 3-wire serial I/O mode with automatic transmit/receive function (SCK1...Internal clock output)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|----------------|---|----------------|------|----------------|------|
| SCK1 cycle time | tkcY11 | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 800 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.5 V | 1,600 | | | ns |
| SCK1 high-/low-level width | tkH11, tkL11 | $V_{DD} = 4.5 \text{ to } 5.5 \text{ V}$ | tксү11/2 - 50 | | | ns |
| | | | tkcy11/2 - 100 | | | ns |
| SI1 setup time (to SCK1↑) | tsik11 | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 100 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.5 V | 150 | | | ns |
| SI1 hold time (from SCK1↑) | tksi11 | | 400 | | | ns |
| SO1 output delay time from SCK1↓ | t KSO11 | C = 100 pF ^{Note} | | | 300 | ns |
| STB↑ from SCK1↑ | tsbD | | tkcy11/2 - 100 | | tксү11/2 + 100 | ns |
| Strobe signal high-level width | tssw | 2.7 V ≤ V _{DD} < 5.5 V | tксү11 – 30 | | tксү11 + 30 | ns |
| Busy signal setup time (to busy signal detection timing) | tBYS | | 100 | | | ns |
| Busy signal hold time | tвүн | 4.5 V ≤ V _{DD} ≤ 5.5 V | 100 | | | ns |
| (from busy signal detection timing) | | 2.7 V ≤ V _{DD} < 4.5 V | 150 | | | ns |
| SCK1 ↓ from busy inactive | tsps | | | | 2tксү11 | ns |

Note C is the load capacitance of the $\overline{SCK1}$ and SO1 output lines.

(iv) 3-wire serial I/O mode with automatic transmit/receive function (SCK1...External clock input)

| Parameter | Symbol | Con | ditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------------|-------------------------------------|--|---------------------------------|-------|------|-------|------|
| SCK1 cycle time | t KCY12 | $4.5 \text{ V} \leq \text{V}_{\text{DD}} \leq 5.5$ | V | 800 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.5 V | | 1,600 | | | ns |
| SCK1 high-/low-level width | t кн12, | 4.5 V ≤ V _{DD} ≤ 5.5 V | | 400 | | | ns |
| | t KL12 | 2.7 V ≤ V _{DD} < 4.5 | 2.7 V ≤ V _{DD} < 4.5 V | | | | ns |
| SI1 setup time (to SCK1 ↑) | tsik12 | V _{DD} = 2.7 to 5.5 \ | V _{DD} = 2.7 to 5.5 V | | | | ns |
| SI1 hold time (from SCK1↑) | t KSI12 | | | 400 | | | ns |
| SO1 output delay time from SCK1↓ | t KSO12 | C = 100 pF ^{Note} | V _{DD} = 2.7 to 5.5 V | | | 300 | ns |
| SCK1 rise/fall time | t _{R12} , t _{F12} | When using external device expansion function | | | | 160 | ns |
| | | When not using e expansion function | | | | 1,000 | ns |

Note C is the load capacitance of the SO1 output line.

(c) Serial interface channel 2

(i) 3-wire serial I/O mode (SCK2...Internal clock output)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|----------------|--|----------------|------|------|------|
| SCK2 cycle time | t KCY13 | $4.5~V \leq V_{DD} \leq 5.5~V$ | 800 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 1,600 | | | ns |
| SCK2 high-/low-level width | t кн13, | V _{DD} = 4.5 to 5.5 V | tксү13/2 - 50 | | | ns |
| | t KL13 | | tксү13/2 - 100 | | | ns |
| SI2 setup time (to \$\overline{SCK2}\overline{\chi}\$) | t SIK13 | $4.5~V \leq V_{DD} \leq 5.5~V$ | 100 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 150 | | | ns |
| SI2 hold time (from SCK2↑) | t KSI13 | | 400 | | | ns |
| SO2 output delay time from $\overline{\text{SCK2}} \downarrow$ | t KSO13 | C = 100 pF ^{Note} | | | 300 | ns |

Note C is the load capacitance of the SO2 output line.

(ii) 3-wire serial I/O mode (SCK2...External clock input)

| Parameter | Symbol | Coi | nditions | MIN. | TYP. | MAX. | Unit |
|--|--------------------|--|--------------------------------|-------|------|------|------|
| SCK2 cycle time | tkCY14 | 4.5 V ≤ V _{DD} ≤ 5.5 | V | 800 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.5 | V | 1,600 | | | ns |
| SCK2 high-/low-level width | t кн14, | 4.5 V ≤ V _{DD} ≤ 5.5 | V | 400 | | | ns |
| | tKL14 | 2.7 V ≤ V _{DD} < 4.5 | V | 800 | | | ns |
| SI2 setup time (to SCK2 ↑) | tsik14 | V _{DD} = 2.7 to 5.5 V | | 100 | | | ns |
| SI2 hold time (from SCK2↑) | tksi14 | | | 400 | | | ns |
| SO2 output delay time from SCK2 ↓ | t KSO14 | C = 100 pFNote | V _{DD} = 2.7 to 5.5 V | | | 300 | ns |
| SCK2 rise/fall time | t _{R14} , | Other than below | , | | | 160 | ns |
| | tF14 | V _{DD} = 4.5 to 5.5 V When not using external device expansion function | | | | 1 | μs |

Note C is the load capacitance of the SO2 output line.



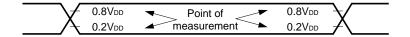
(iii) UART mode (Dedicated baud rate generator output)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------|--------|---|------|------|--------|------|
| Transfer rate | | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | | | 78,125 | bps |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | | | 39,063 | bps |

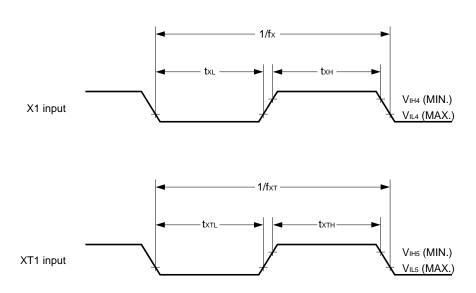
(iv) UART mode (External clock input)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------|-------------------------------------|--|-------|------|--------|------|
| ASCK cycle time | tKCY15 | $4.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 800 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 1,600 | | | ns |
| ASCK high-/low-level width | t KH15, t KL15 | $4.5~\textrm{V} \leq \textrm{V}_\textrm{DD} \leq 5.5~\textrm{V}$ | 400 | | | ns |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | 800 | | | ns |
| Transfer rate | | $4.5~\textrm{V} \leq \textrm{V}_\textrm{DD} \leq 5.5~\textrm{V}$ | | | 39,063 | bps |
| | | $2.7 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V}$ | | | 19,531 | bps |
| ASCK rise/fall time | t _{R15} , t _{F15} | V _{DD} = 4.5 to 5.5 V, | | | 1,000 | ns |
| | | when not using external device | | | | |
| | | expansion function. | | | | |
| | | | | | 160 | ns |

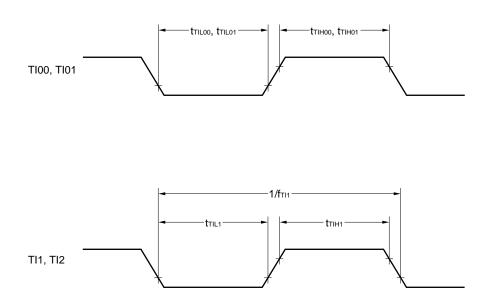
AC Timing Measurement Points (Excluding X1, XT1 Inputs)



Clock Timing

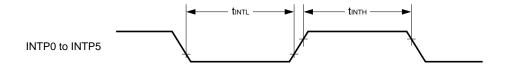


TI Timing

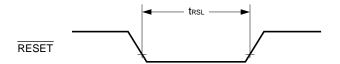




Interrupt Request Input Timing

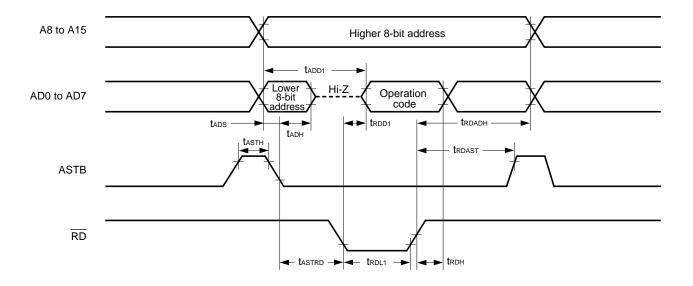


RESET Input Timing

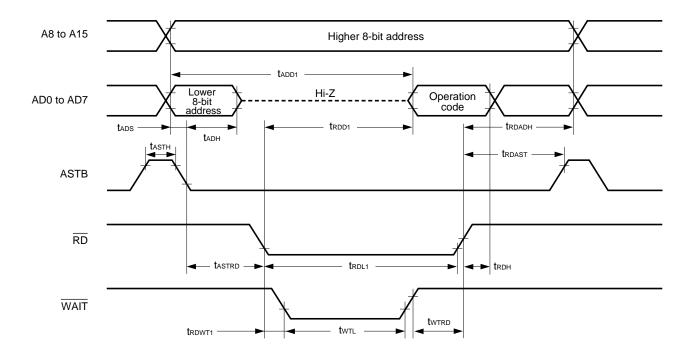


Read/Write Operation

External fetch (no wait):

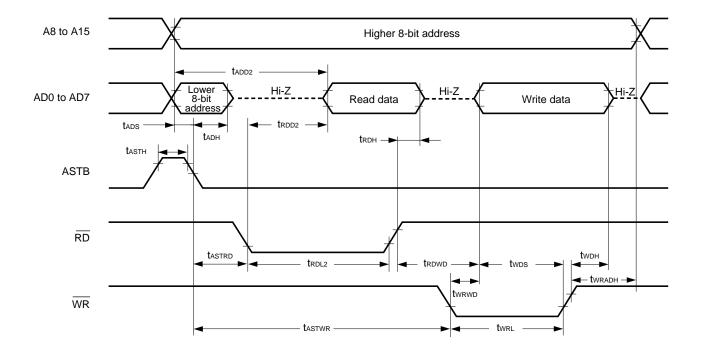


External fetch (wait insertion):

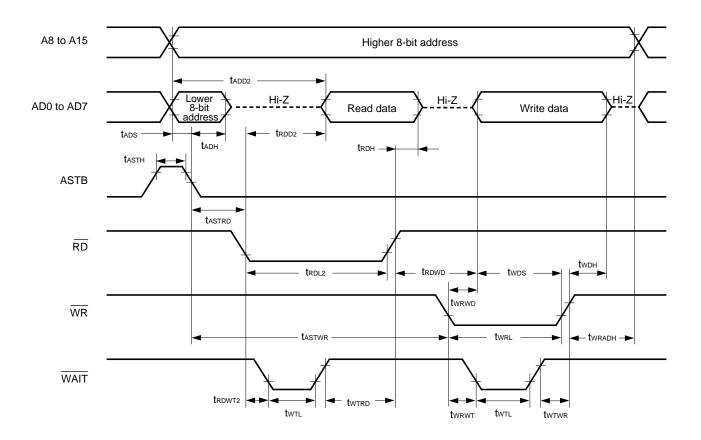




External data access (no wait):



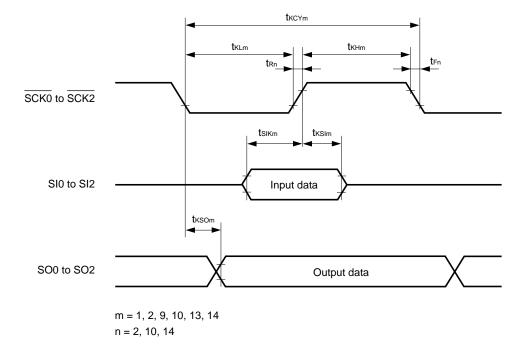
External data access (wait insertion):



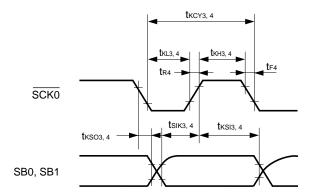


Serial Transfer Timing

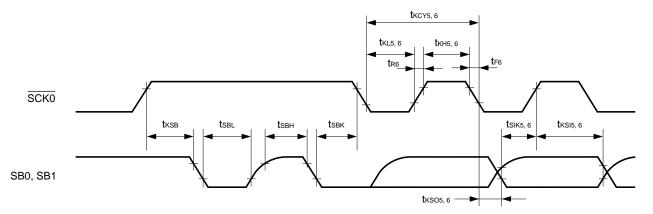
3-wire serial I/O mode:



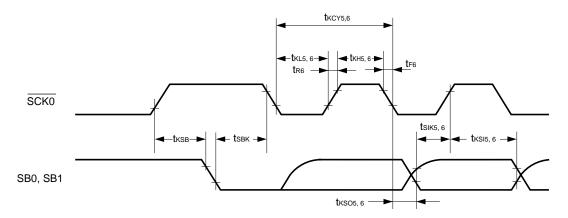
2-wire serial I/O mode:



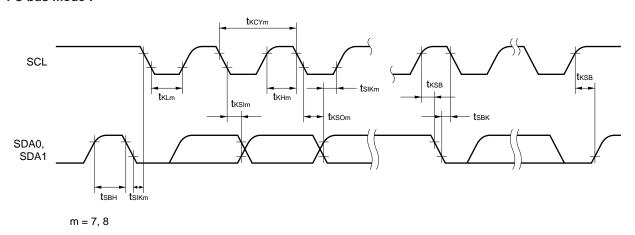
SBI mode (bus release signal transfer):



SBI mode (command signal transfer):

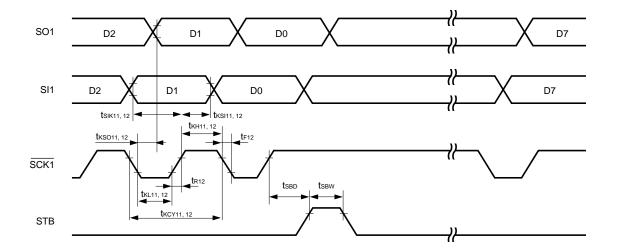


I²C bus mode:

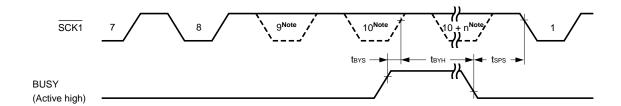




3-wire serial I/O mode with automatic transmit/receive function:

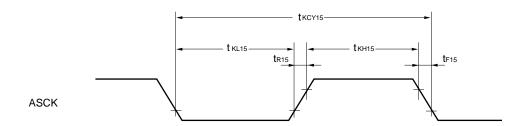


3-wire serial I/O mode with automatic transmit/receive function (busy processing):



Note The signal is not actually driven low here; it is shown as such to indicate the timing.

UART mode (external clock input):





A/D Converter Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$, $AV_{SS} = V_{SS} = 0 \text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------|--------------------|--|------|------|--------------------|------|
| Resolution | | | 8 | 8 | 8 | bit |
| Overall error ^{Note 1} | | 2.7 V ≤ AV _{REF0} < 4.5 V | | | ±1.0 | % |
| | | 4.5 V ≤ AV _{REF0} < 5.5 V | | | ±0.6 | % |
| Conversion time | TCONV | 2.7 V ≤ AV _{REF0} < 5.5 V | 16 | | 100 | μs |
| Analog input voltage | VIAN | | AVss | | AV _{REF0} | V |
| Reference voltage | AV _{REF0} | | 2.7 | | V _{DD} | V |
| AVREFO current | I _{REF0} | When A/D converter is operating Note 2 | | 500 | 1,500 | μΑ |
| | | When A/D converter is not operating Note 3 | | 0 | 3 | μΑ |

Notes 1. Excludes quantization error (±1/2 LSB). This value is indicated as a ratio to the full-scale value.

- 2. The current flowing to the AVREFO pin when bit 7 (CS) of the A/D converter mode register (ADM) is 1.
- 3. The current flowing to the AVREFO pin when bit 7 (CS) of the A/D converter mode register (ADM) is 0.

D/A Converter Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$, $AV_{SS} = V_{SS} = 0 \text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------------|--------------------|--------------------------------------|------|------|-----------------|------|
| Resolution | | | | | 8 | bit |
| Overall error | | $R = 2 M\Omega^{\text{Note 1}}$ | | | ±1.2 | % |
| | | $R = 4 M\Omega^{\text{Note 1}}$ | | | ±0.8 | % |
| | | R = 10 M Ω ^{Note 1} | | | ±0.6 | % |
| Settling time | | C = 30 pF ^{Note 1} | | | 15 | μs |
| Output resistance | Ro | Note 2 | | 8 | | kΩ |
| Analog reference voltage | AV _{REF1} | | 1.8 | | V _{DD} | V |
| AV _{REF1} current | I _{REF1} | Note 2 | | | 2.5 | mA |
| Resistance between AVREF1 and AVSS | RAIREF1 | DACS0, DACS1 = 55H ^{Note 2} | 4 | 8 | | kΩ |

Notes 1. R and C are the D/A converter output pin load resistance and load capacitance, respectively.

2. Value for one D/A converter channel

Remark DACS0 and DACS1: D/A conversion value setting registers 0, 1



Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics (TA = -40 to +85°C)

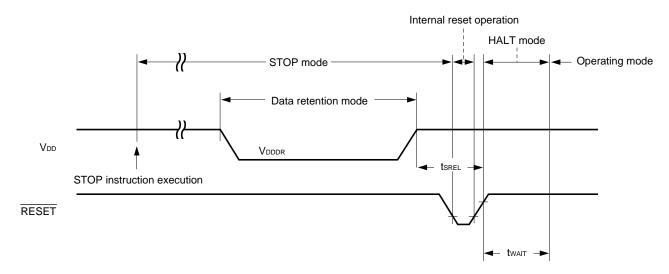
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|--------|--|------|--------|------|------|
| Data retention power supply voltage | VDDDR | | 1.8 | | 5.5 | V |
| Data retention power supply current | IDDDR | V _{DDDR} = 1.8 V Subsystem clock stop and feed-back resistor disconnected | | 0.1 | 10 | μΑ |
| Release signal set time | tsrel | | 0 | | | μs |
| Oscillation stabilization | twait | Release by RESET | | 217/fx | | ms |
| wait time | | Release by interrupt request | | Note | | ms |

Note Selection of 2¹²/fxx and 2¹⁴/fxx to 2¹⁷/fxx is possible with bits 0 to 2 (OSTS0 to OSTS2) of the oscillation stabilization time select register (OSTS).

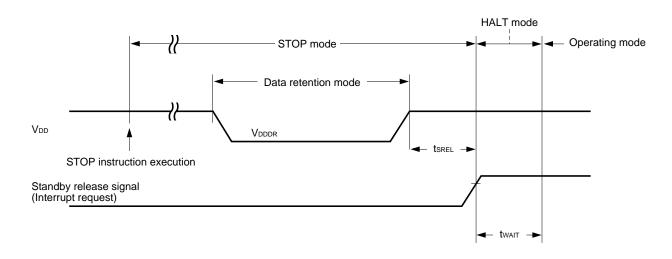
Remark fxx: Main system clock frequency (fx or fx/2)

fx: Main system clock oscillation frequency

Data Retention Timing (STOP Mode Release by RESET)



Data Retention Timing (Standby Release Signal: STOP Mode Release by Interrupt Request Signal)





Flash Memory Programming Characteristics (V_{DD} = 2.7 to 5.5 V, T_A = 10 to 40°C)

(1) Write/delete characteristics

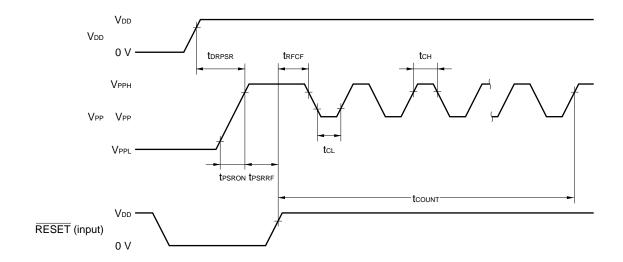
| Parameter | Symbol | | Conditions | MIN. | TYP. | MAX. | Unit |
|---|------------------|---|--|------|------|---------------------|-------|
| Write current (V _{DD} pin) ^{Note 1} | todw | When Vpp = Vpp1 | 5.0 MHz crystal oscillation operation mode (fxx = 2.5 MHz) ^{Note 2} | | | 15.5 | mA |
| | | | 5.0 MHz crystal oscillation operation mode (fxx = 5.0 MHz)Note 3 | | | 28.7 | mA |
| Write current (VPP pin)Note 1 | IPPW | When VPP = VPP1 | 5.0 MHz crystal oscillation operation mode (fxx = 2.5 MHz) ^{Note 2} | | | 19.5 | mA |
| | | | 5.0 MHz crystal oscillation operation mode (fxx = 5.0 MHz)Note 3 | | | 32.7 | mA |
| Delete current (VDD pin)Note 1 | IDDE | When V _{PP} = V _{PP1} | 5.0 MHz crystal oscillation operation mode (fxx = 2.5 MHz) ^{Note 2} | | | 15.5 | mA |
| | | | 5.0 MHz crystal oscillation operation mode (fxx = 5.0 MHz)Note 3 | | | 28.7 | mA |
| Delete current (VPP pin)Note 1 | IPPE | When VPP = VPP1 | | | | 100 | mA |
| Unit delete time | ter | | | 0.5 | 1 | 1 | S |
| Total delete time | tera | | | | | 20 | s |
| Number of overwrite | Cwrt | Delete and write are counted as one cycle | | | | 20 | times |
| VPP power supply voltage | V _{PP0} | In normal mode | In normal mode | | | 0.2 V _{DD} | V |
| | V _{PP1} | At flash memory pr | ogramming | 9.7 | 10.0 | 10.3 | V |

- Notes 1. 1. AVREF current and Port current (current flowing to internal pull-up resistor) are not included.
 - **2.** When main system clock is operating at fxx = fxx/2 (when oscillation mode selection resistor (OSMS) is set to 00H).
 - **3.** When main system clock is operating at fxx = fxx (when OSMS is set to 01H).

2) Serial write operation characteristics

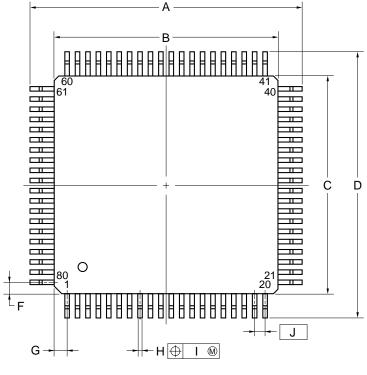
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|----------------|------------------------------|------|------|------|------|
| VPP setup time | tpsron | VPP high voltage | 1.0 | | | μs |
| V _{PP} ↑ setup time from V _{DD} ↑ | t DRPSR | VPP high voltage | 1.0 | | | μs |
| RESET↑ setup time from V _{PP} ↑ | t psrrf | V _{PP} high voltage | 1.0 | | | μs |
| V _{PP} count start time from RESET↑ | trfcf | | 1.0 | | | μs |
| Count execution time | tcount | | | | 2.0 | ms |
| V _{PP} counter high-level width | tсн | | 8.0 | | | μs |
| V _{PP} counter low-level width | tcL | | 8.0 | | | μs |
| VPP counter noise elimination width | tnfw | | | 40 | | ns |

Flash Write Mode Setting Timing

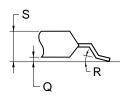


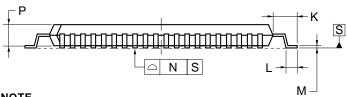
8. PACKAGE DRAWINGS

80-PIN PLASTIC QFP (14x14)



detail of lead end



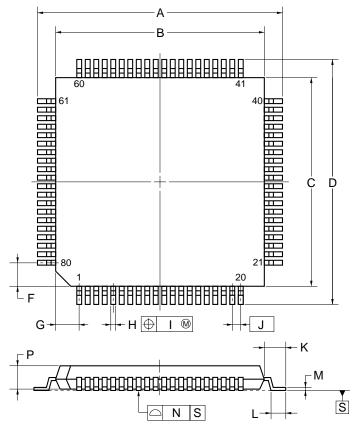


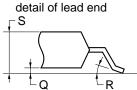
NOTE

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS |
|------|------------------------|
| Α | 17.20±0.20 |
| В | 14.00±0.20 |
| С | 14.00±0.20 |
| D | 17.20±0.20 |
| F | 0.825 |
| G | 0.825 |
| Н | 0.32±0.06 |
| I | 0.13 |
| J | 0.65 (T.P.) |
| K | 1.60±0.20 |
| L | 0.80±0.20 |
| М | $0.17^{+0.03}_{-0.07}$ |
| N | 0.10 |
| Р | 1.40±0.10 |
| Q | 0.125±0.075 |
| R | 3°+7° -3° |
| S | 1.70 MAX. |
| | D90GC-65-9BT-1 |

80 PIN PLASTIC TQFP (FINE PITCH) (12x12)





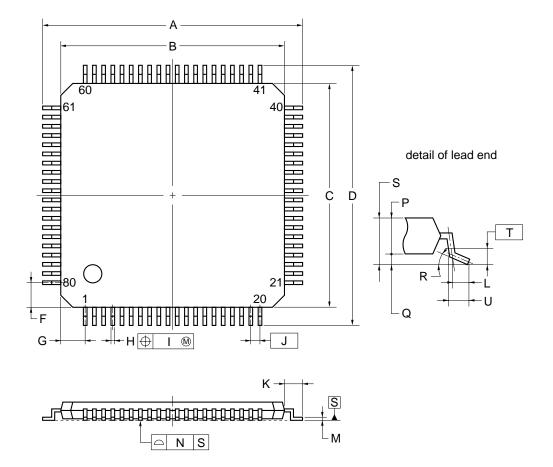
NOTE

Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS |
|------|---------------------------|
| Α | 14.00±0.20 |
| В | 12.00±0.20 |
| С | 12.00±0.20 |
| D | 14.00±0.20 |
| F | 1.25 |
| G | 1.25 |
| Н | $0.22^{+0.05}_{-0.04}$ |
| I | 0.10 |
| J | 0.50 (T.P.) |
| K | 1.00±0.20 |
| L | 0.50±0.20 |
| М | $0.145^{+0.055}_{-0.045}$ |
| N | 0.10 |
| Р | 1.05±0.07 |
| Q | 0.10±0.05 |
| R | 5°±5° |
| S | 1.27 MAX. |
| | DOGGIC EG DEG |

P80GK-50-BE9-6

★ 80-PIN PLASTIC TQFP (FINE PITCH) (12x12)



NOTE

Each lead centerline is located within 0.08 mm of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS |
|------|---------------|
| Α | 14.0±0.2 |
| В | 12.0±0.2 |
| С | 12.0±0.2 |
| D | 14.0±0.2 |
| F | 1.25 |
| G | 1.25 |
| Н | 0.22±0.05 |
| 1 | 0.08 |
| J | 0.5 (T.P.) |
| K | 1.0±0.2 |
| L | 0.5 |
| M | 0.145±0.05 |
| N | 0.08 |
| Р | 1.0 |
| Q | 0.1±0.05 |
| R | 3°+4° -3° |
| S | 1.1±0.1 |
| Т | 0.25 |
| U | 0.6±0.15 |
| | P80GK-50-9EU- |

P80GK-50-9EU-

9. RECOMMENDED SOLDERING CONDITIONS

The μ PD78F0058 and 78F0058Y should be soldered and mounted under the following recommended conditions.

For the details of the recommended soldering conditions, refer to the document **Semiconductor Device Mounting Technology Manual (C10535E)**.

For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Table 9-1. Surface Mounting Type Soldering Conditions

 $\mu \text{PD78F0058GC-8BT}$: 80-pin plastic QFP (14 \times 14 mm) $\mu \text{PD78F0058YGC-8BT}$: 80-pin plastic QFP (14 \times 14 mm)

| Soldering Method | Soldering Conditions | Recommended Condition Symbol |
|---------------------|---|------------------------------|
| | Parlamental transporture 200000 Time 200 accessed to the Cat O40000 and interest | , |
| Infrared reflow | Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Twice or less | IR35-00-2 |
| VPS | Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Twice or less | VP15-00-2 |
| Wave soldering | Solder bath temperature: 260°C max., Time: 10 seconds max., Count: Once, Preheating temperature: 120°C max. (package surface temperature) | WS60-00-1 |
| Partial heating | Pin temperature: 300°C max., Time: 3 seconds max. (per pin row) | _ |

Caution Do not use different soldering methods together (except for partial heating).

 μ PD78F0058GK-BE9: 80-pin plastic TQFP (12 × 12 mm, resin thickness 1.05 mm) μ PD78F0058YGK-BE9: 80-pin plastic TQFP (12 × 12 mm, resin thickness 1.05 mm)

| Soldering | Soldering Conditions | Recommended |
|-----------------|---|------------------|
| Method | | Condition Symbol |
| Infrared reflow | Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Twice or less, Exposure limit: 7 days ^{Note} | IR35-107-2 |
| | (after 7 days, prebake at 125°C for 10 hours) | |
| VPS | Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Twice or less, Exposure limit: 7 days ^{Note} (after 7 days, prebake at 125°C for 10 hours) | VP15-107-2 |
| Wave soldering | - | - |
| Partial heating | Pin temperature: 300°C max., Time: 3 seconds max. (per pin row) | _ |

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).



 μ PD78F0058GK-9EU : 80-pin plastic TQFP (12 \times 12 mm, resin thickness 1.0 mm) μ PD78F0058YGK-9EU : 80-pin plastic TQFP (12 \times 12 mm, resin thickness 1.0 mm)

| Soldering | Soldering Conditions | Recommended |
|-----------------|---|------------------|
| Method | | Condition Symbol |
| Infrared reflow | Undefined | Undefined |
| VPS | Undefined | Undefined |
| Wave soldering | Undefined | Undefined |
| Partial heating | Pin temperature: 300°C max., Time: 3 seconds max. (per pin row) | _ |

★ APPENDIX A. DEVELOPMENT TOOLS

The following development tools are available for system development using the μ PD780058, 780058Y Subseries.

Also, refer to (5) Cautions on using development tools.

(1) Language processing software

| RA78K0 | Assembler package common to the 78K/0 Series |
|----------|---|
| CC78K0 | C compiler package common to the 78K/0 Series |
| DF780058 | Device file for the μ PD780058, 780058Y Subseries |
| CC78K0-L | C compiler library source file common to the 78K/0 Series |

(2) Flash memory writing tools

| | Flashpro III (Part number: | Dedicated flash programmer for microcontrollers incorporating flash memory |
|-----------------|----------------------------|--|
| FL-PR3, PG-FL3) | | |
| | FA-80GC-8BT | Adapter for flash memory writing |
| | FA-80GK | |
| | FA-80GK-9EU | |
| | | |

(3) Debugging tools

• When using the IE-78K0-NS in-circuit emulator

| IE-78K0-NS | In-circuit emulator common to the 78K/0 Series | | |
|------------------|---|--|--|
| IE-70000-MC-PS-B | Power supply unit for IE-78K0-NS | | |
| IE-78K0-NS-PA | Performance board to enhance and expand the functions of the IE-78K0-NS | | |
| IE-70000-98-IF-C | Adapter used when a PC-9800 series PC (except notebook PC) is used as the host machine (C bus supported) | | |
| IE-70000-CD-IF-A | PC card and interface cable used when a PC-9800 series notebook PC is used as the host machine (PCMCIA socket supported) | | |
| IE-70000-PC-IF-C | Adapter necessary when an IBM PC/AT TM -compatible is used as the host machine (ISA bus supported) | | |
| IE-70000-PCI-IF | Interface adapter necessary when using a PC with PCI bus as the host machine | | |
| IE-780308-NS-EM1 | Emulation board common to the μ PD780308 Subseries | | |
| NP-80GC | Emulation probe for 80-pin plastic QFP (GC-8BT type) | | |
| NP-80GK | Emulation probe for 80-pin plastic TQFP (GK-BE9, GK-9EU type) | | |
| TGK-080SDW | Conversion adapter to connect the NP-80GK and a target system board on which 80-pin plastic TQFP (GK-BE9, GK-9EU type) can be mounted | | |
| EV-9200GC-80 | Socket to be mounted on a target system board made for 80-pin plastic QFP (GC-8BT type) | | |
| ID78K0-NS | Integrated debugger for IE-78K0-NS | | |
| SM78K0 | System simulator common to the 78K/0 Series | | |
| DF780058 | Device file for the μ PD780058, 780058Y Subseries | | |

• When using the IE-78001-R-A in-circuit emulator

| IE-78001-R-A | In-circuit emulator common to the 78K/0 Series |
|------------------------------------|---|
| IE-70000-98-IF-C | Adapter used when PC-9800 series PC (except notebook type) is used as host machine (C bus supported) |
| IE-70000-PC-IF-C | Interface adapter when using IBM PC/AT-compatible as the host machine (ISA bus supported) |
| IE-78000-R-SV3 | Interface adapter and cable used when EWS is used as the host machine |
| IE-780308-NS-EM1 IE-780308-R-EM | Emulation board common to the μ PD780308 Subseries |
| IE-78K0-R-EX1 | Emulation probe conversion board necessary when using the IE-780308-NS-EM1 on the IE-78001-R-A. |
| EP-78230GC-R | Emulation probe for 80-pin plastic QFP (GC-8BT type) |
| EP-78054GK-R | Emulation probe for 80-pin plastic TQFP (GK-BE9, GK-9EU type) |
| TGK-080SDW | Conversion adapter to connect the EP-78054GK-R and a target system on which an 80-pin plastic TQFP (GK-BE9, GK-9EU type) can be mounted |
| EV-9200GC-80 | Socket to be mounted on a target system board made for 80-pin plastic QFP (GC-8BT type) |
| ID78K0 | Integrated debugger for IE-78001-R-A |
| SM78K0 | 78K/0 Series common system simulator |
| DF780058 | Device file for the μPD780058, 780058Y Subseries |

(4) Real-time OS

| RX78K/0 | Real-time OS for the 78K/0 Series |
|---------|-----------------------------------|
| MX78K0 | OS for the 78K/0 Series |

(5) Cautions on using development tools

- The ID78K0-NS, ID78K0, and SM78K0 are used in combination with the DF780058.
- The CC78K0 and RX78K/0 are used in combination with the RA78K0 and DF780058.
- The FL-PR3, FA-80GC-8BT, FA-80GK, FA80GK-9EU, NP-80GC, and NP-80GK are products of Naito Densei Machida Mfg. Co., Ltd. (TEL: +81-44-822-3813). Contact an NEC distributor regarding the purchase of these products.
- TGK-080SDW is a product made by Tokyo Eletech Corp.

For further information, contact Daimaru Kogyo, Ltd.

Electronics Department (Tokyo) (TEL: +81-3-3820-7112)

Electronics 2nd Department (Osaka) (TEL: +81-6-6244-6672)

- For third-party development tools, see the Single-Chip Microcontroller Development Tool Selection Guide (U11069E)
- The host machine and OS suitable for each software are as follows:

| Host Machine [OS] | PC | EWS |
|-------------------|------------------------------------|--|
| | PC-9800 Series [Japanese Windows™] | HP9000 series 700™ [HP-UX™] |
| | IBM PC/AT-compatible | SPARCstation™ [SunOS™ ,Solaris™] |
| Software | [Japanese/English Windows] | NEWS [™] (RISC) [NEWS-OS [™]] |
| RA78K0 | √Note | \checkmark |
| CC78K0 | √Note | \checkmark |
| ID78K0-NS | V | - |
| ID78K0 | V | \checkmark |
| SM78K0 | V | _ |
| RX78K/0 | √Note | V |
| MX78K0 | √Note | V |

Note DOS-based software

★ APPENDIX B. RELATED DOCUMENTS

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

Documents Related to Devices

| Document Name Document No | | ment No. |
|--|----------|---------------|
| | Japanese | English |
| μPD780058, 780058Y Subseries User's Manual | U12013J | U12013E |
| μPD780053, 780054, 780055, 780056, 780058 Data Sheet | U12182J | U12182E |
| μPD78F0058, 78F0058Y Data Sheet | U12092J | This document |
| 78K/0 Series User's Manual - Instruction | U12326J | U12326E |
| 78K/0 Series Instruction Table | U10903J | _ |
| 78K/0 Series Instruction Set | U10904J | _ |
| 78K/0, 78K/0S Series Flash Memory Write Application Note | U14458J | U14458E |

Documents Related to Development Tools (User's Manuals)

| Document Name | | Document No. | |
|--|---|----------------|----------------|
| | | Japanese | English |
| RA78K0 Assembler Package | Operation | U11802J | U11802E |
| | Assembly Language | U11801J | U11801E |
| | Structured Assembly Language | U11789J | U11789E |
| RA78K Series Structured Assembler Preprocessor | | U12323J | EEU-1402 |
| CC78K0 C Compiler | Operation | U11517J | U11517E |
| | Language | U11518J | U11518E |
| IE-78K0-NS | | U13731J | U13731E |
| IE-78001-R-EM | | To be prepared | To be prepared |
| IE-780308-NS-EM1 | | To be prepared | To be prepared |
| IE-780308-R-EM | | U11362J | U11362E |
| EP-78230 | | EEU-985 | EEU-1515 |
| EP-78054GK-R | | U13630J | _ |
| SM78K0 System Simulator Windows Based | Reference | U10181J | U10181E |
| SM78K Series System Simulator | External Part User Open Interface Specifications | U10092J | U10092E |
| ID78K0-NS Integrated Debugger Windows Based | Reference | U12900J | U12900E |
| ID78K0 Integrated Debugger EWS Based | Reference | U11151J | - |
| ID78K0 Integrated Debugger PC Based | Reference | U11539J | U11539E |
| ID78K0 Integrated Debugger Windows Based | Guide | U11649J | U11649E |

Caution The related documents listed above are subject to change without notice. Be sure to use the latest version of each document for designing.

Documents Related to Embedded Software (User's Manuals)

| Document Name | | Document No. | |
|---------------------------|--------------|--------------|---------|
| | | Japanese | English |
| 78K/0 Series Real-Time OS | Fundamentals | U11537J | U11537E |
| | Installation | U11536J | U11536E |
| 78K/0 Series OS MX78K0 | Fundamental | U12257J | U12257E |

Other Related Documents

| Document Name | Document No. | |
|--|--------------|---------|
| | Japanese | English |
| SEMICONDUCTORS SELECTION GUIDE Products & Packages (CD-ROM) | X13769X | |
| Semiconductor Device Mounting Technology Manual | C10535J | C10535E |
| Quality Grades on NEC Semiconductor Devices | C11531J | C11531E |
| NEC Semiconductor Device Reliability/Quality Control System | C10983J | C10983E |
| Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD) | C11892J | C11892E |
| Guide to Microcomputer-Related Products by Third Party | U11416J | _ |

Caution The related documents listed above are subject to change without notice. Be sure to use the latest version of each document for designing.

NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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- · Device availability
- · Ordering information
- · Product release schedule
- Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- · Network requirements

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 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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